Total Dose Radiation Test Report

MSK 5810 RH
(MSK5800RH, MSK5820RH, MSK5821RH, MSK5822RH, MSK 5827RH)
RAD Hard Ultra Low Dropout
Adjustable Positive Linear Regulator

November 25, 2008 (MSK 5810RH – 1st Test)
Updated on December 24, 2008
March 21, 2009 (MSK 5822RH – 1st Test)
March 26, 2009 (MSK 5810RH – 2nd Test)
September 3, 2009 (MSK 5810RH – 3rd Test)
November 6, 2009 (MSK 5810RH – 4th Test)
May 14, 2010 (MSK 5810RH – 5th Test)

M. Bilecki
B. Erwin

M.S. Kennedy Corporation
Liverpool, NY

I. Introduction:

The total dose radiation test plan for the MSK 5810 RH series was developed to qualify the devices as RAD Hard to 300 KRAD (Si). The testing was performed beyond 300 KRAD (Si) to show trends in device performance as a function of total dose. The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the specified total dose level. The MSK 5800RH, MSK5810RH, MSK5820RH, MSK5821RH, MSK5822RH, and MSK5827RH all use the same active components. The data in this report is from direct measurement of the MSK5810RH response to irradiation but it is indicative of the response of all five device types and is applicable to all five types.

MIL-STD-883 Method 1019.7 and ASTM F1892-06 were used as guidelines in the development and implementation of the total dose test plan for the MSK 5810RH.

II. Radiation Source:

Total dose was performed at the University of Massachusetts, Lowell, using a cobalt 60 radiation source. The dose rate was determined to be 138 Rads(Si)/sec. The total dose schedule can be found in Table I.

III. Test Setup:

All test samples were subjected to Group A Electrical Test at 25°C in accordance with the device data sheet. In addition, all devices received 320 hours of burn-in per MIL-STD-883 Method 1015. For test platform verification, one control device was tested at 25°C. Ten devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

The devices were vertically aligned with the radiation source and enclosed in a lead/aluminum container during irradiation. Five devices were biased during irradiation. Maximum recommended operating voltage of +7.5V was used for the bias condition. Five devices had all leads grounded during irradiation for the unbiased condition.

After each irradiation the device leads were shorted together and transported to the MSK automatic electrical test platform and tested IAW MSK device data sheet. Testing was performed on irradiated devices, as well as the control device, at each total dose level. Electrical tests were completed within one hour of irradiation. Devices were subjected to subsequent radiation doses within two hours of removal from the radiation field.

IV. Data:

All performance curves are averaged from the test results of the biased and unbiased devices, respectively. If required, full test data can be obtained by contacting M.S. Kennedy Corporation.

V. Summary:

Based on the test data recorded during radiation testing, the MSK5810RH qualified as a 300 KRAD (Si) radiation hardened device. Feedback Voltage, Shutdown Threshold, and Output Current Limit exhibited the most significant shift due to irradiation, however all performance curves stayed within specification up to 450 KRAD (Si) TID.

MSK 5810RH Biased/Unbiased Dose Rate Schedule

Dosimetry Equipment
Bruker Biospin # 0141

Irradiation Date
05/14/10

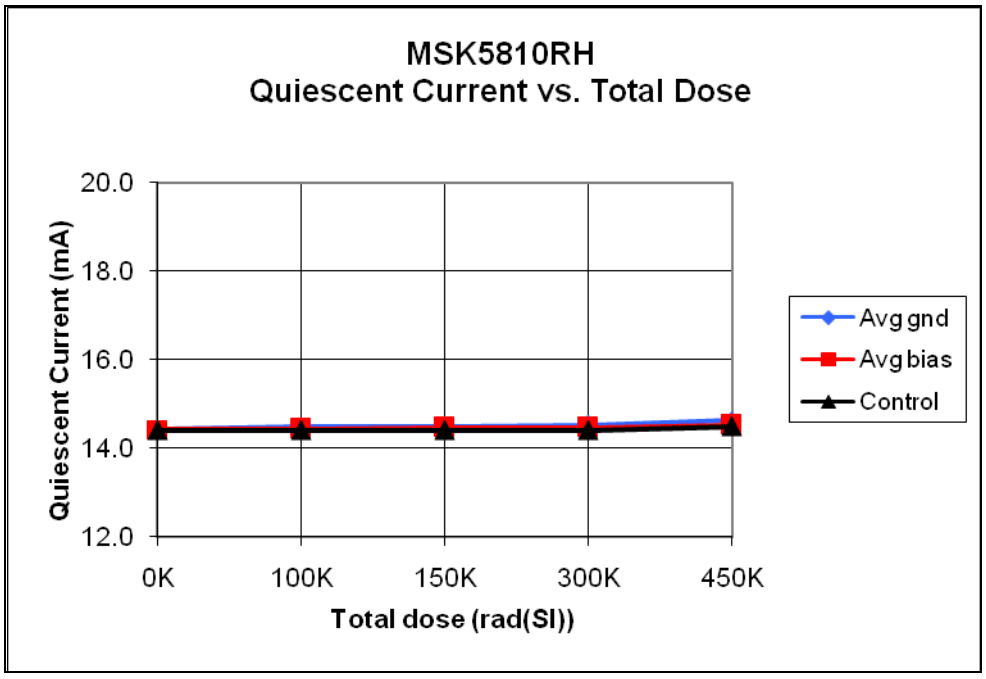
Exposure Length (min:sec)	Incremental Dose rads(Si)	Cumulative Dose rads(Si)
12:27	103,086	103,086
6:14	51,612	154,698
18:40	154,560	309,258
18:40	154,560	463,818

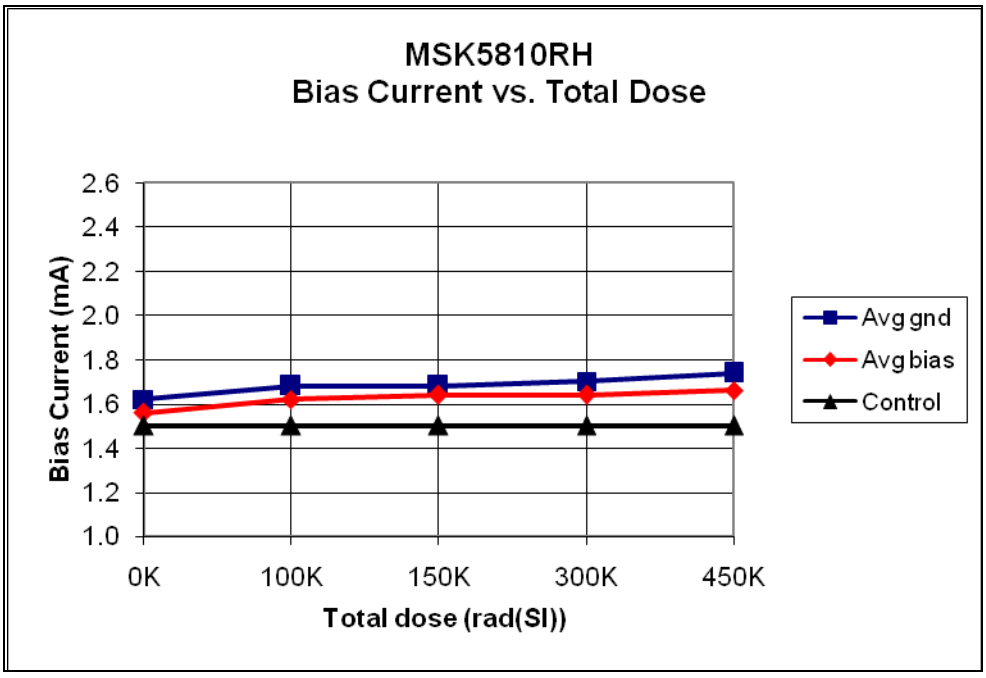
Biased S/N – 0360, 0361, 0362, 0363, 0364

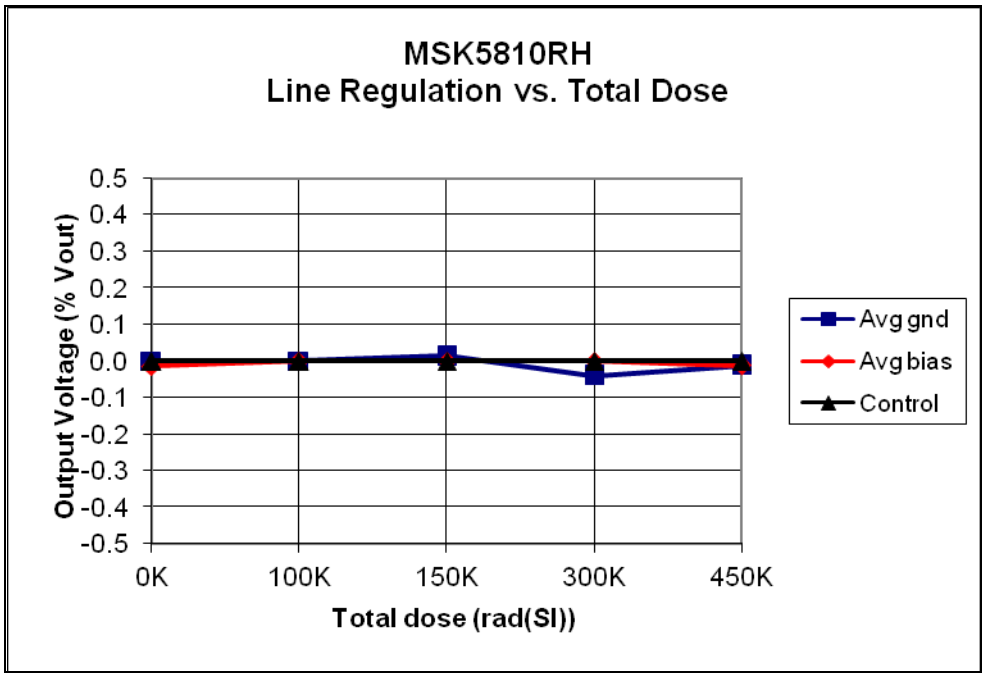
Unbiased S/N – 0365, 0366, 0367, 0368, 0369

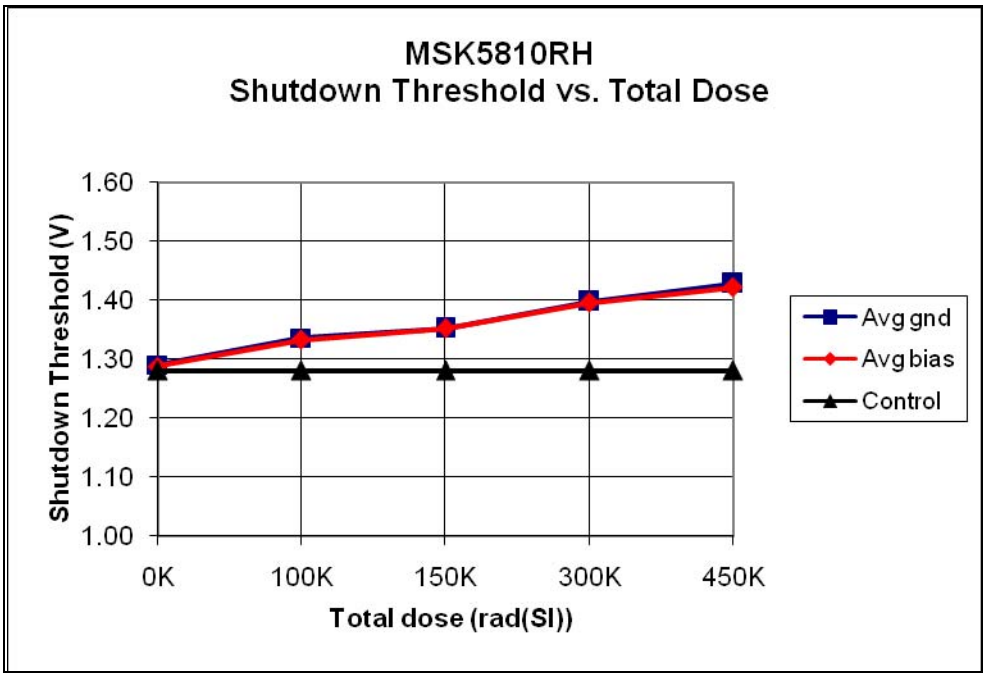
Table 1

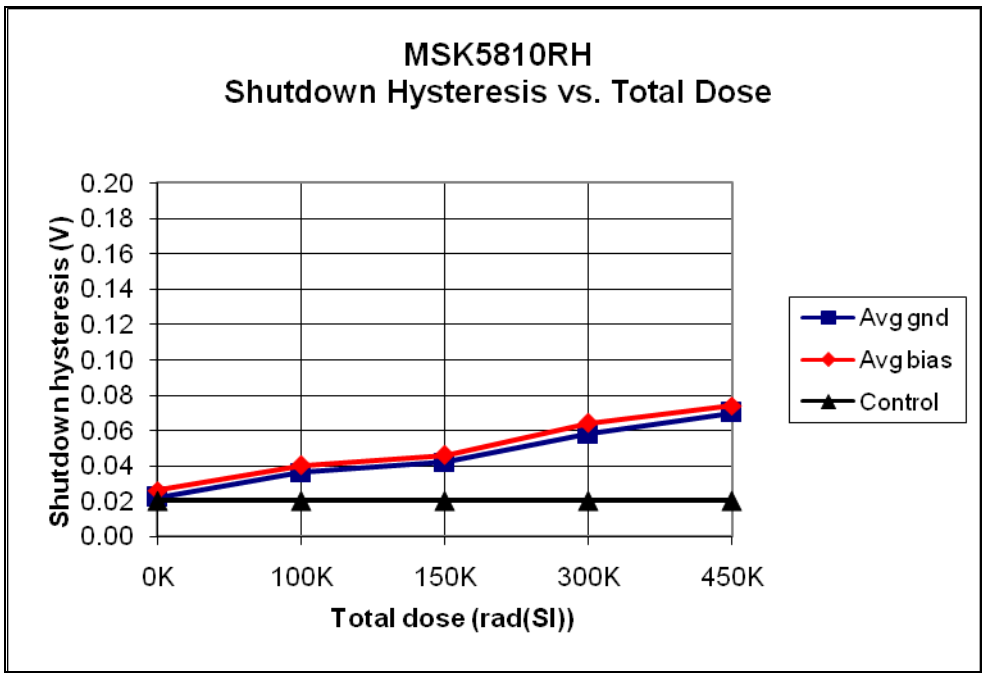
Dose Time, Incremental Dose and Total Cumulative Dose

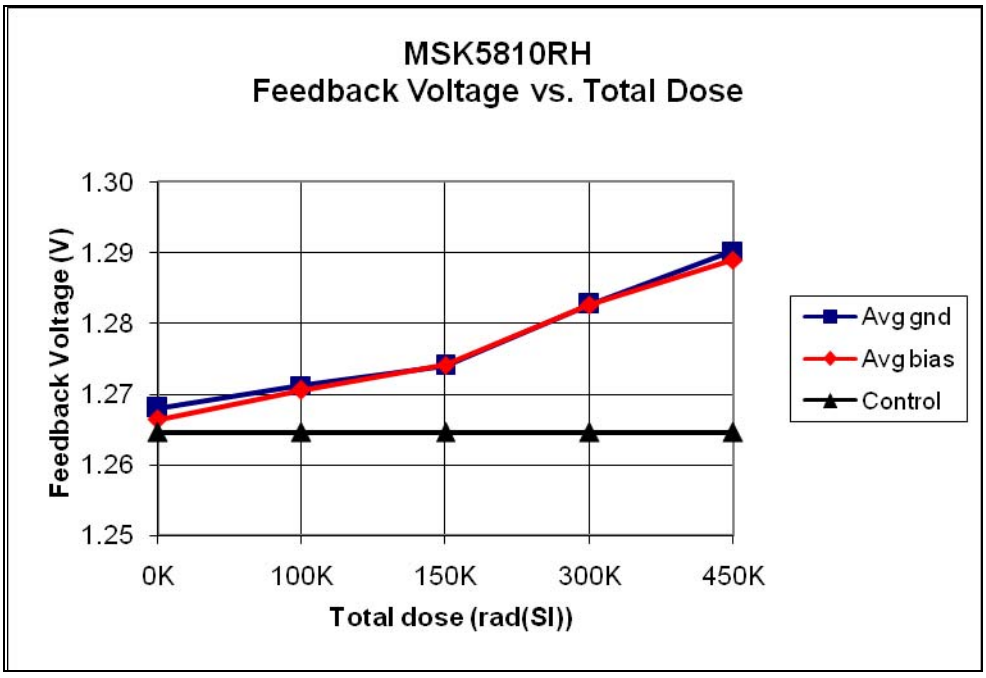

MSK5810RH
Quiescent Current vs. Total Dose
Quiescent Current (mA)
20.0
18.0
16.0
14.0
12.0
0K
100K
150K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control

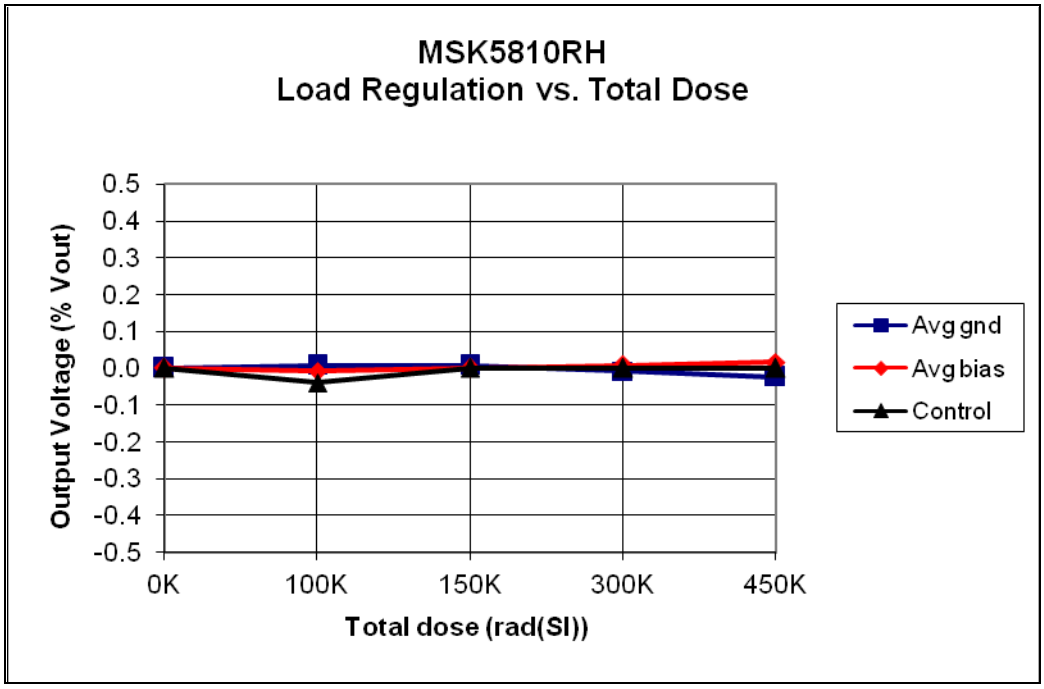

MSK5810RH
Bias Current vs. Total Dose
Bias Current (mA)
2.6
2.4
2.2
2.0
1.8
1.6
1.4
1.2
1.0
0K
100K
150K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control

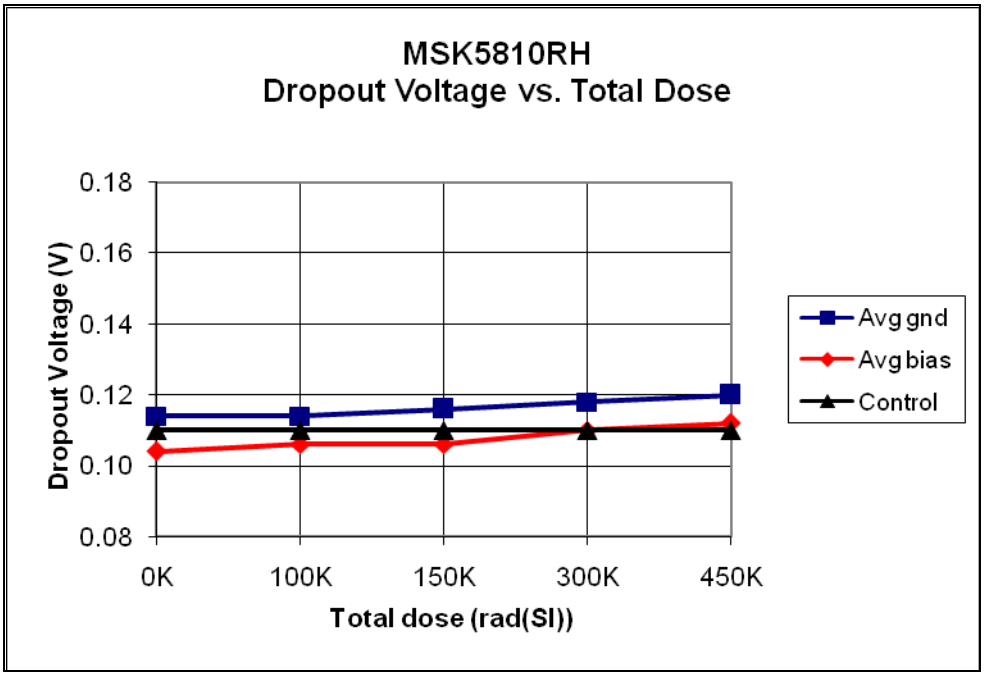

MSK5810RH
Line Regulation vs. Total Dose
Output Voltage (% Vout)
0.5
0.4
0.3
0.2
0.1
0.0
-0.1
-0.2
-0.3
-0.4
-0.5
0K
100K
150K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control

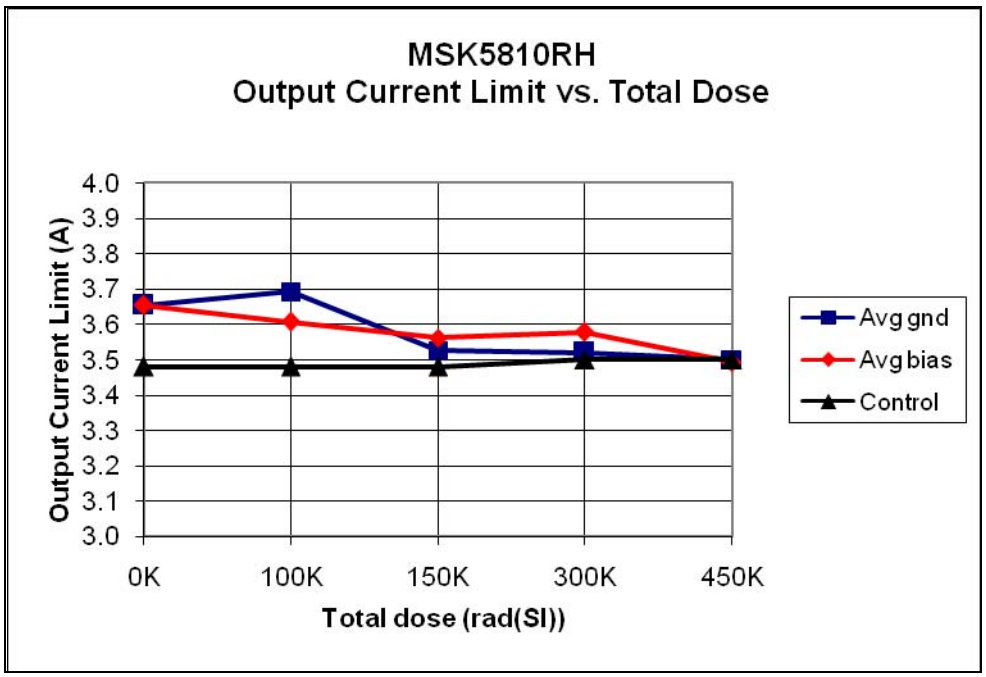

MSK5810RH
Shutdown Threshold vs. Total Dose
Shutdown Threshold (V)
1.60
1.50
1.40
1.30
1.20
1.10
1.00
0K
100K
150K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control


MSK5810RH
Shutdown Hysteresis vs. Total Dose
Shutdown hysteresis (V)
0.20
0.18
0.16
0.14
0.12
0.10
0.08
0.06
0.04
0.02
0.00
0K
100K
150K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control


MSK5810RH
Feedback Voltage vs. Total Dose
Feedback Voltage (V)
1.30
1.29
1.28
1.27
1.26
1.25
0K
100K
150K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control


MSK5810RH
Load Regulation vs. Total Dose
Output Voltage (% Vout)
0.5
0.4
0.3
0.2
0.1
0.0
-0.1
-0.2
-0.3
-0.4
-0.5
0K
100K
150K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control


MSK5810RH
Dropout Voltage vs. Total Dose
Dropout Voltage (V)
0.18
0.16
0.14
0.12
0.10
0.08
0K
100K
150K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control


MSK5810RH
Output Current Limit vs. Total Dose
Output Current Limit (A)
4.0
3.9
3.8
3.7
3.6
3.5
3.4
3.3
3.2
3.1
3.0
0K
100K
150K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control

Total Dose Radiation Test Report

MSK 5810 RH
(MSK5800RH, MSK5820RH, MSK5821RH, MSK5822RH, MSK 5827RH)
RAD Hard Ultra Low Dropout
Adjustable Positive Linear Regulator

November 25, 2008 (MSK 5810RH – 1st Test)
Updated on December 24, 2008
March 21, 2009 (MSK 5822RH – 1st Test)
March 26, 2009 (MSK 5810RH – 2nd Test)
September 3, 2009 (MSK 5810RH – 3rd Test)
November 6, 2009 (MSK 5810RH – 4th Test)

M. Bilecki
B. Erwin

M.S. Kennedy Corporation
Liverpool, NY

I. Introduction:

The total dose radiation test plan for the MSK 5810 RH series was developed to qualify the devices as RAD Hard to 300 KRAD (Si). The testing was performed beyond 300 KRAD (Si) to show trends in device performance as a function of total dose. The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the specified total dose level. The MSK 5800RH, MSK5810RH, MSK5820RH, MSK5821RH, MSK5822RH, and MSK5827RH all use the same active components. The data in this report is from direct measurement of the MSK5810RH response to irradiation but it is indicative of the response of all five device types and is applicable to all five types.

MIL-STD-883 Method 1019.7 and ASTM F1892-06 were used as guidelines in the development and implementation of the total dose test plan for the MSK 5810RH.

II. Radiation Source:

Total dose was performed at the University of Massachusetts, Lowell, using a cobalt 60 radiation source. The dose rate was determined to be 156 Rads(Si)/sec. The total dose schedule can be found in Table I.

III. Test Setup:

All test samples were subjected to Group A Electrical Test at 25°C in accordance with the device data sheet. In addition, all devices received 320 hours of burn-in per MIL-STD-883 Method 1015. For test platform verification, one control device was tested at 25°C. Ten devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

The devices were vertically aligned with the radiation source and enclosed in a lead/aluminum container during irradiation. Five devices were biased during irradiation. Maximum recommended operating voltage of +7.5V was used for the bias condition. Five devices had all leads grounded during irradiation for the unbiased condition.

After each irradiation the device leads were shorted together and transported to the MSK automatic electrical test platform and tested IAW MSK device data sheet. Testing was performed on irradiated devices, as well as the control device, at each total dose level. Electrical tests were completed within one hour of irradiation. Devices were subjected to subsequent radiation doses within two hours of removal from the radiation field.

IV. Data:

All performance curves are averaged from the test results of the biased and unbiased devices, respectively. If required, full test data can be obtained by contacting M.S. Kennedy Corporation.

V. Summary:

Based on the test data recorded during radiation testing, the MSK5810RH qualified as a 300 KRAD (Si) radiation hardened device. Feedback Voltage, Shutdown Threshold, and Output Current Limit exhibited the most significant shift due to irradiation, however all performance curves stayed within specification up to 450 KRAD (Si) TID.

MSK 5810RH Biased/Unbiased Dose Rate Schedule

Dosimetry Equipment
Bruker Biospin # 0141

Irradiation Date
11/06/09

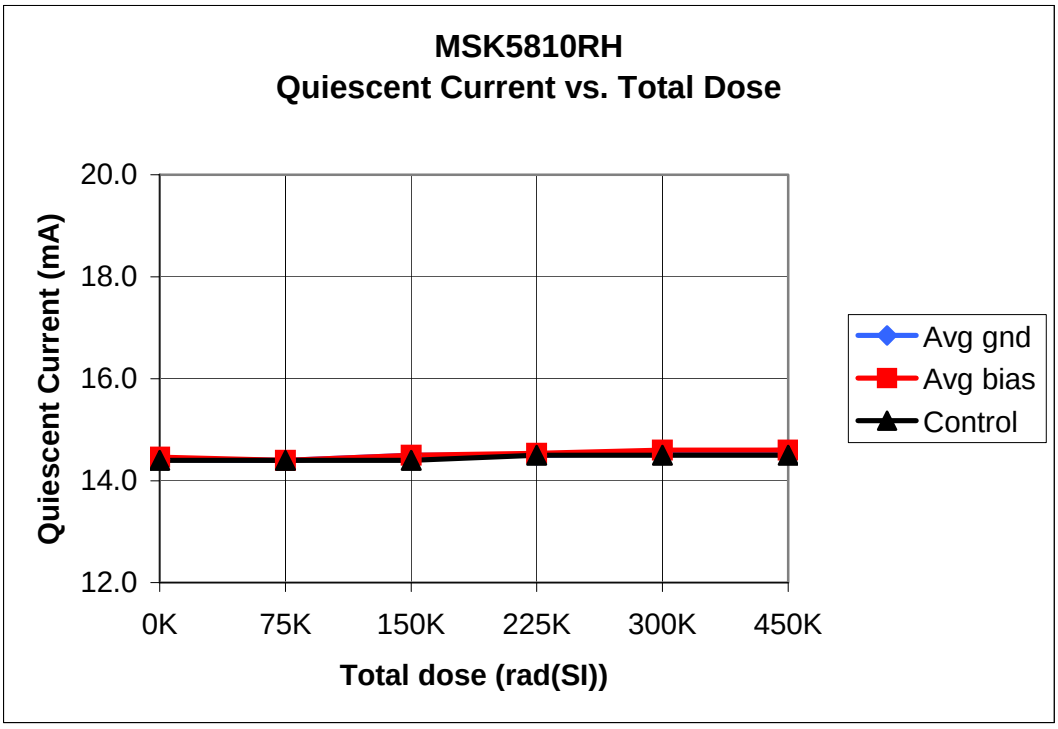
Exposure Length (min:sec)	Incremental Dose rads(Si)	Cumulative Dose rads(Si)
8:16	77,376	77,376
8:16	77,376	154,752
8:16	77,376	232,128
8:16	77,376	309,504
16:32	154,752	464,256

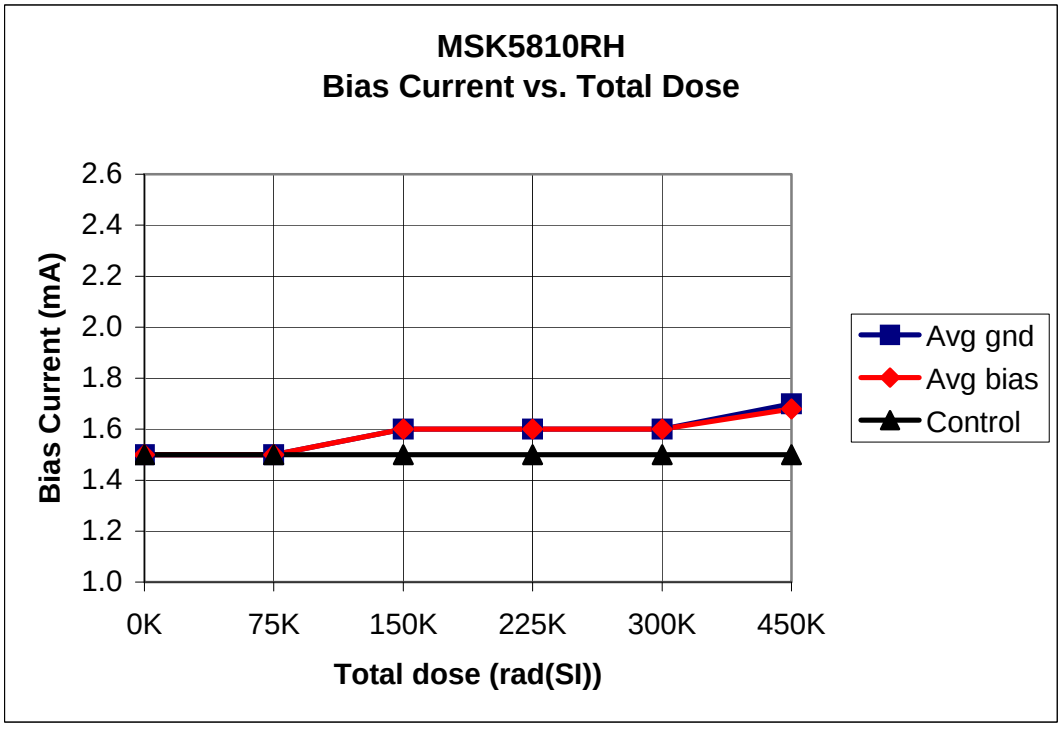
Biased S/N – 0315, 0316, 0317, 0318, 0319

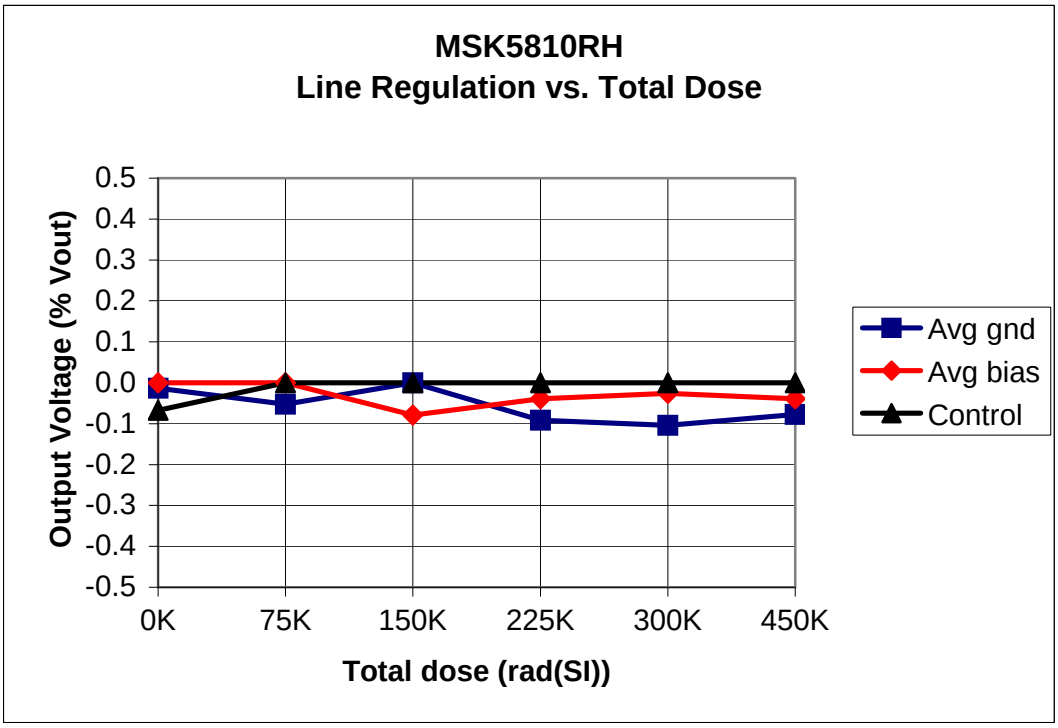
Unbiased S/N – 0320, 0321, 0322, 0324, 0325

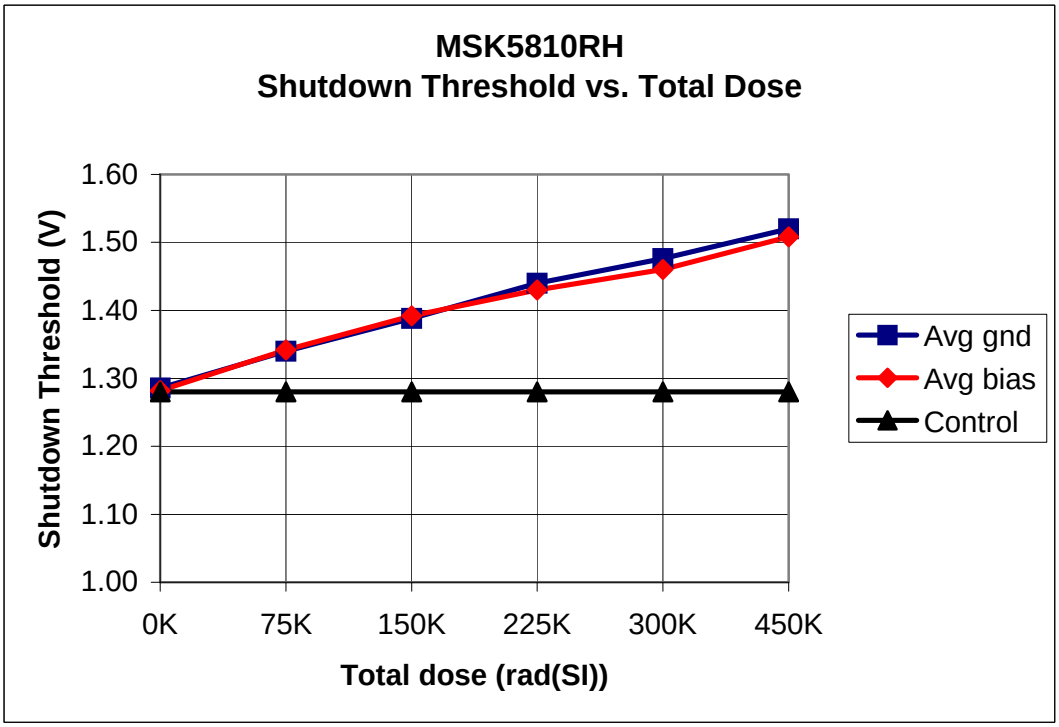
Table 1

Dose Time, Incremental Dose and Total Cumulative Dose

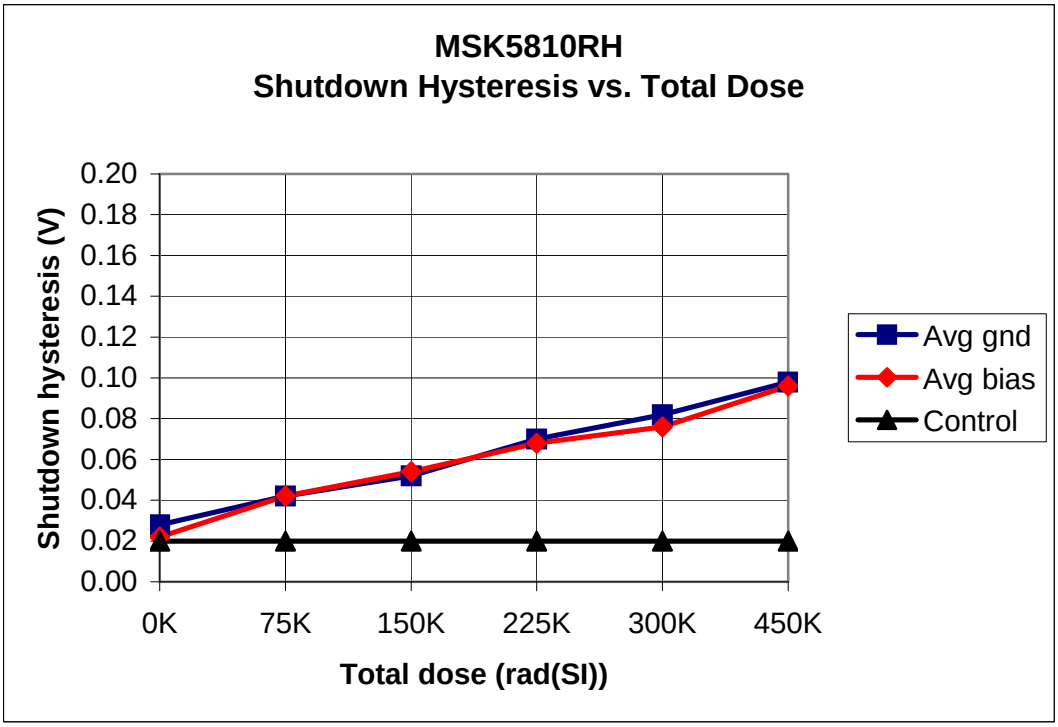

MSK5810RH
Quiescent Current vs. Total Dose
Quiescent Current (mA)
20.0
18.0
16.0
14.0
12.0
0K
75K
150K
225K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control

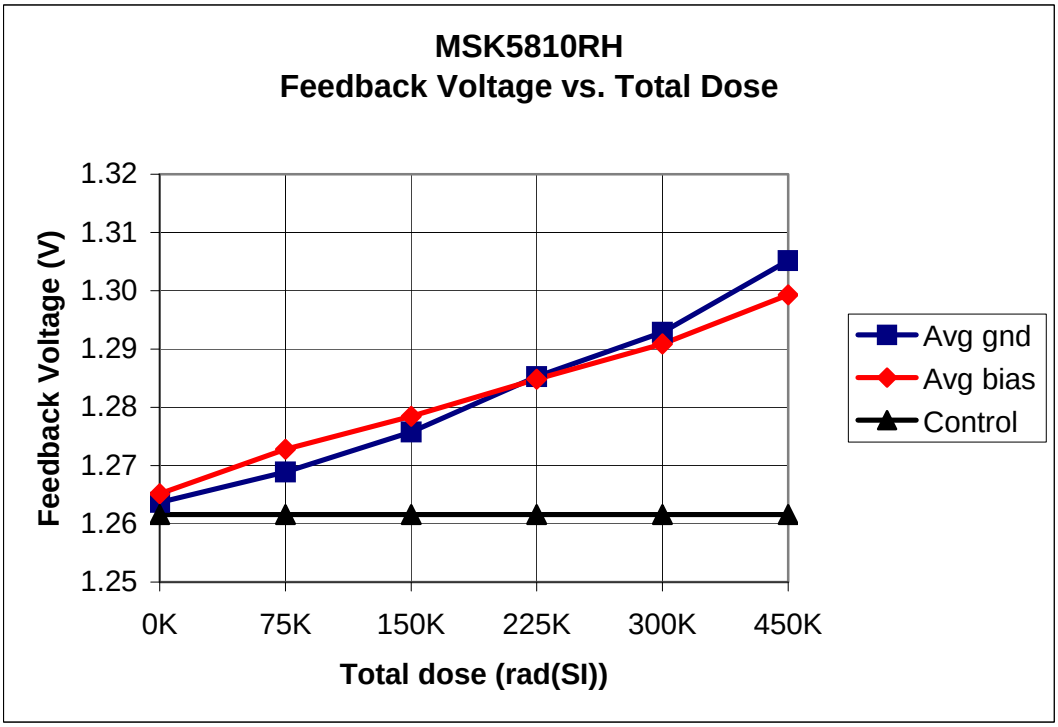

MSK5810RH
Bias Current vs. Total Dose
Bias Current (mA)
2.6
2.4
2.2
2.0
1.8
1.6
1.4
1.2
1.0
0K
75K
150K
225K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control

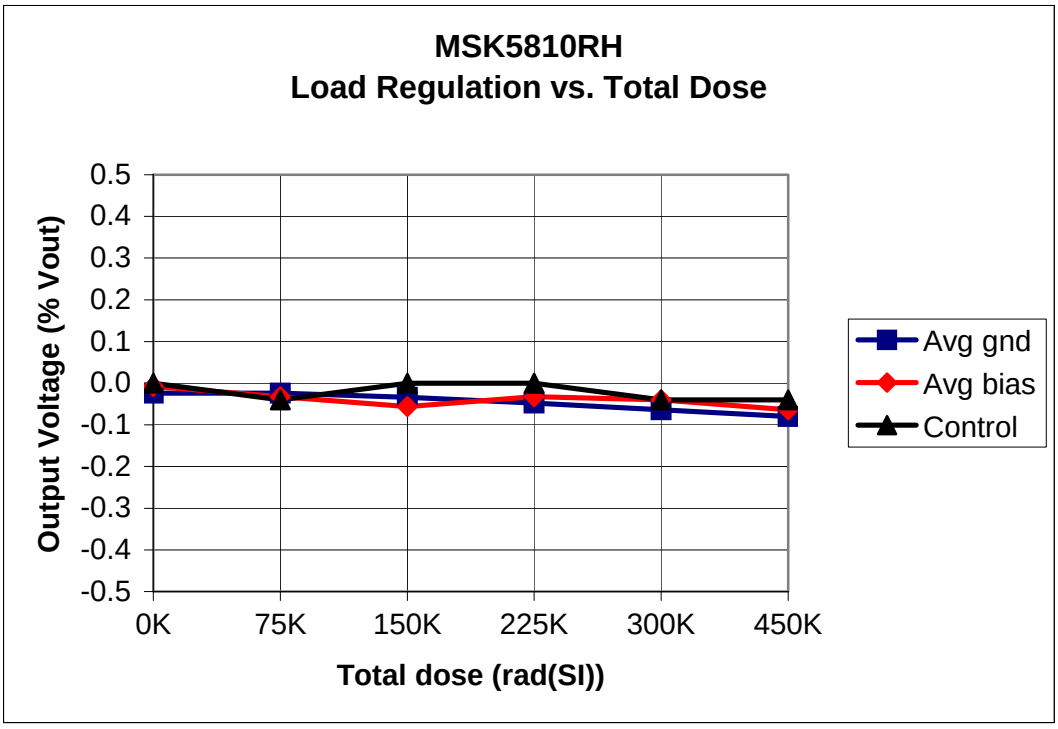

MSK5810RH
Line Regulation vs. Total Dose
Output Voltage (% Vout)
0.5
0.4
0.3
0.2
0.1
0.0
-0.1
-0.2
-0.3
-0.4
-0.5
0K
75K
150K
225K
300K
450K
Total dose (rad(SI))
Avg gnd
Avg bias
Control

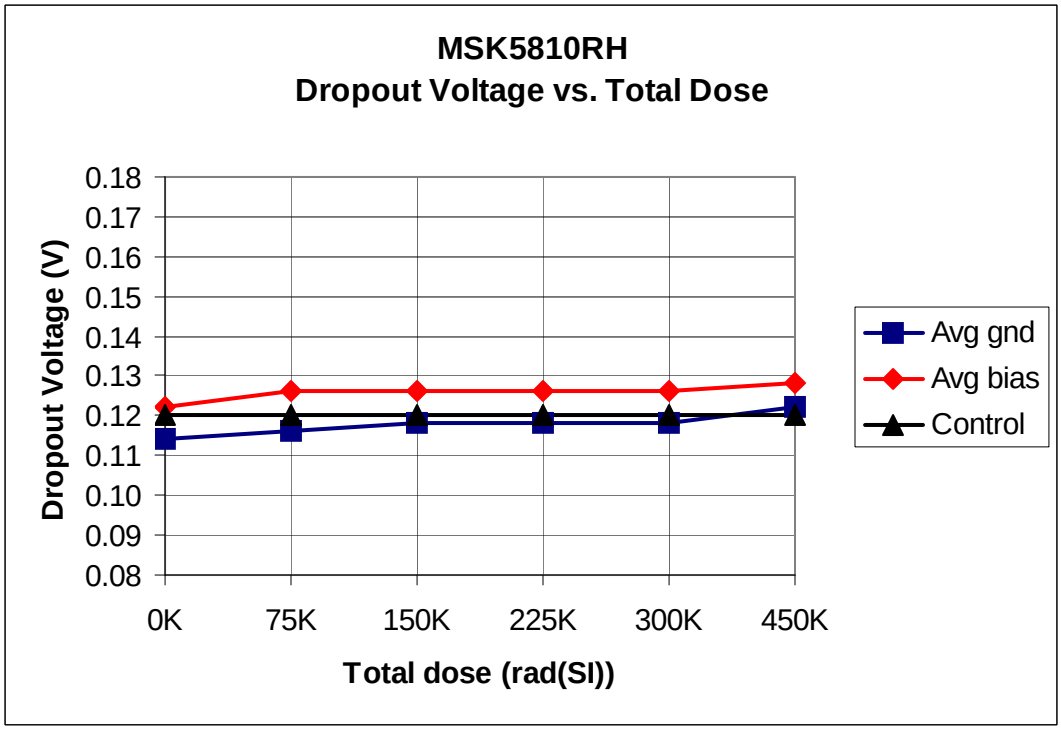

MSK5810RH
Shutdown Threshold vs. Total Dose
Shutdown Threshold (V)
1.60
1.50
1.40
1.30
1.20
1.10
1.00
0K
75K
150K
225K
300K
450K
Total dose (rad(SI))
Avg gnd
Avg bias
Control

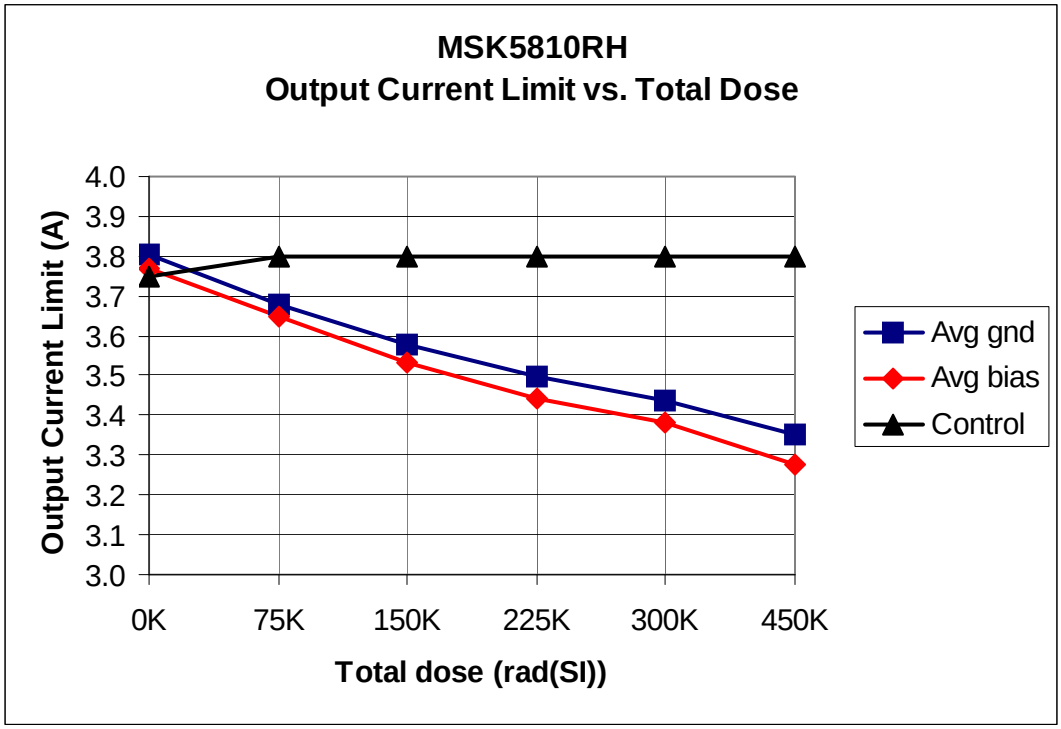
\


MSK5810RH
Shutdown Hysteresis vs. Total Dose
Shutdown hysteresis (V)
0.20
0.18
0.16
0.14
0.12
0.10
0.08
0.06
0.04
0.02
0.00
0K
75K
150K
225K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control


MSK5810RH
Feedback Voltage vs. Total Dose
Feedback Voltage (V)
1.32
1.31
1.30
1.29
1.28
1.27
1.26
1.25
0K
75K
150K
225K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control


MSK5810RH
Load Regulation vs. Total Dose
Output Voltage (% Vout)
0.5
0.4
0.3
0.2
0.1
0.0
-0.1
-0.2
-0.3
-0.4
-0.5
0K
75K
150K
225K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control


MSK5810RH
Dropout Voltage vs. Total Dose
Dropout Voltage (V)
0.18
0.17
0.16
0.15
0.14
0.13
0.12
0.11
0.10
0.09
0.08
0K
75K
150K
225K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control


MSK5810RH
Output Current Limit vs. Total Dose
Output Current Limit (A)
4.0
3.9
3.8
3.7
3.6
3.5
3.4
3.3
3.2
3.1
3.0
0K
75K
150K
225K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control

Total Dose Radiation Test Report

MSK 5810 RH
(MSK5800RH, MSK5820RH, MSK5821RH, MSK5822RH)
RAD Hard Ultra Low Dropout
Adjustable Positive Linear Regulator

November 25, 2008 (First Test)
Updated on December 24, 2008
March 26, 2009 (Second Test)
September 3, 2009 (Third Test)

M. Bilecki
B. Erwin

M.S. Kennedy Corporation
Liverpool, NY

I. Introduction:

The total dose radiation test plan for the MSK 5810 RH series was developed to qualify the devices as RAD Hard to 300 KRAD (Si). The testing was performed beyond 300 KRAD (Si) to show trends in device performance as a function of total dose. The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the specified total dose level. The MSK5800RH, MSK 5810RH, MSK5820RH, MSK5821RH, MSK5822RH, and MSK5827RH all use the same active components. The data in this report is from direct measurement of the MSK5810RH response to irradiation but it is indicative of the response of all five device types and is applicable to all five types.

MIL-STD-883 Method 1019.7 and ASTM F1892-06 were used as guidelines in the development and implementation of the total dose test plan for the MSK 5810RH.

II. Radiation Source:

Total dose was performed at the University of Massachusetts, Lowell, using a cobalt 60 radiation source. The dose rate was determined to be 172 Rads(Si)/sec. The total dose schedule can be found in Table I.

III. Test Setup:

All test samples were subjected to Group A Electrical Test at 25°C in accordance with the device data sheet. In addition, all devices received 320 hours of burn-in per MIL-STD-883 Method 1015. For test platform verification, one control device was tested at 25°C. Ten devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

The devices were vertically aligned with the radiation source and enclosed in a lead/aluminum container during irradiation. Five devices were kept under bias during irradiation. Maximum recommended operating voltage of +7.5V was used for the bias condition. Five devices had all leads grounded during irradiation for the unbiased condition.

After each irradiation the device leads were shorted together and transported to the MSK automatic electrical test platform and tested IAW MSK device data sheet. Testing was performed on irradiated devices, as well as the control device, at each total dose level. Electrical tests were completed within one hour of irradiation. Devices were subjected to subsequent radiation doses within two hours of removal from the radiation field.

IV. Data:

All performance curves are averaged from the test results of the biased and unbiased devices, respectively. If required, full test data can be obtained by contacting M.S. Kennedy Corporation.

V. Summary:

Based on the test data recorded during radiation testing, the MSK5810RH qualified as a 300 KRAD (Si) radiation hardened device. Feedback Voltage, Shutdown Threshold, and Output Current Limit exhibited the most significant shift due to irradiation, however all performance curves stayed within specification up to 450 KRAD (Si) TID.

MSK 5810RH Biased/Unbiased Dose Rate Schedule

Dosimetry Equipment
Bruker Biospin # 0141

Irradiation Date
09/03/09

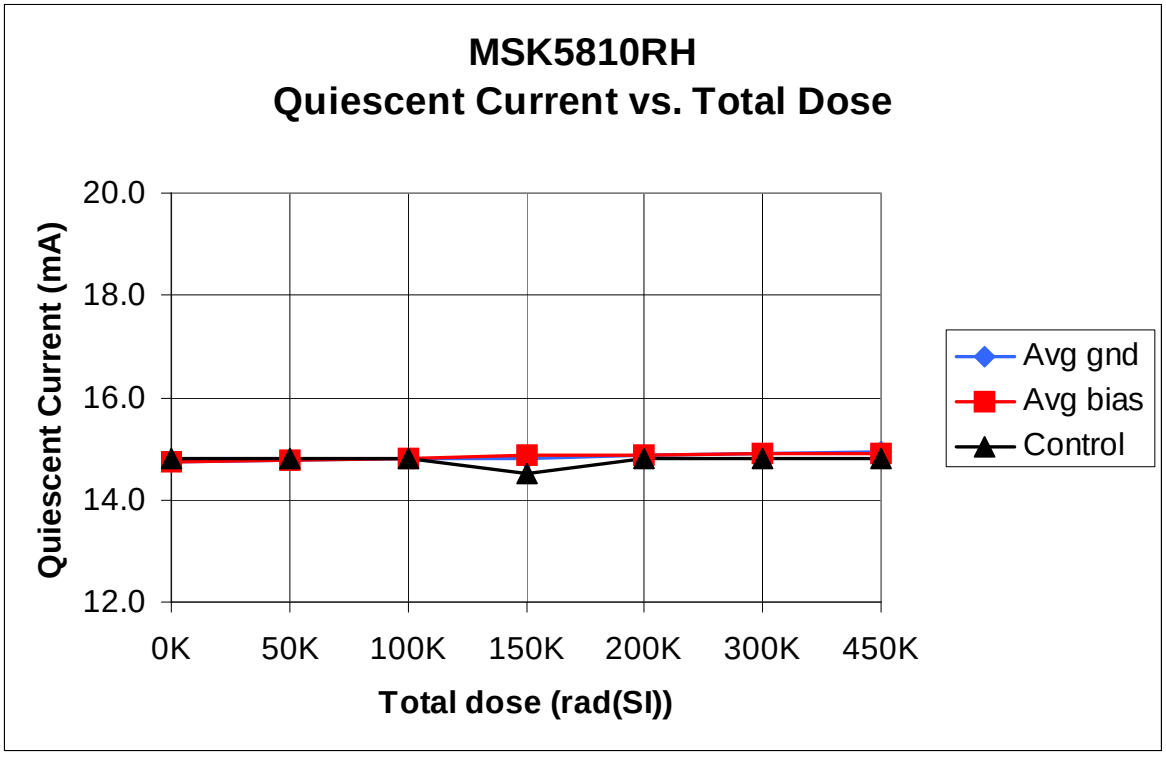
Exposure Length (min:sec)	Incremental Dose rads(Si)	Cumulative Dose rads(Si)
5:00	51,600	51,600
5:00	51,600	103,200
5:00	51,600	154,800
5:00	51,600	206,400
9:59	103,028	309,428
14:58	154,456	463,884

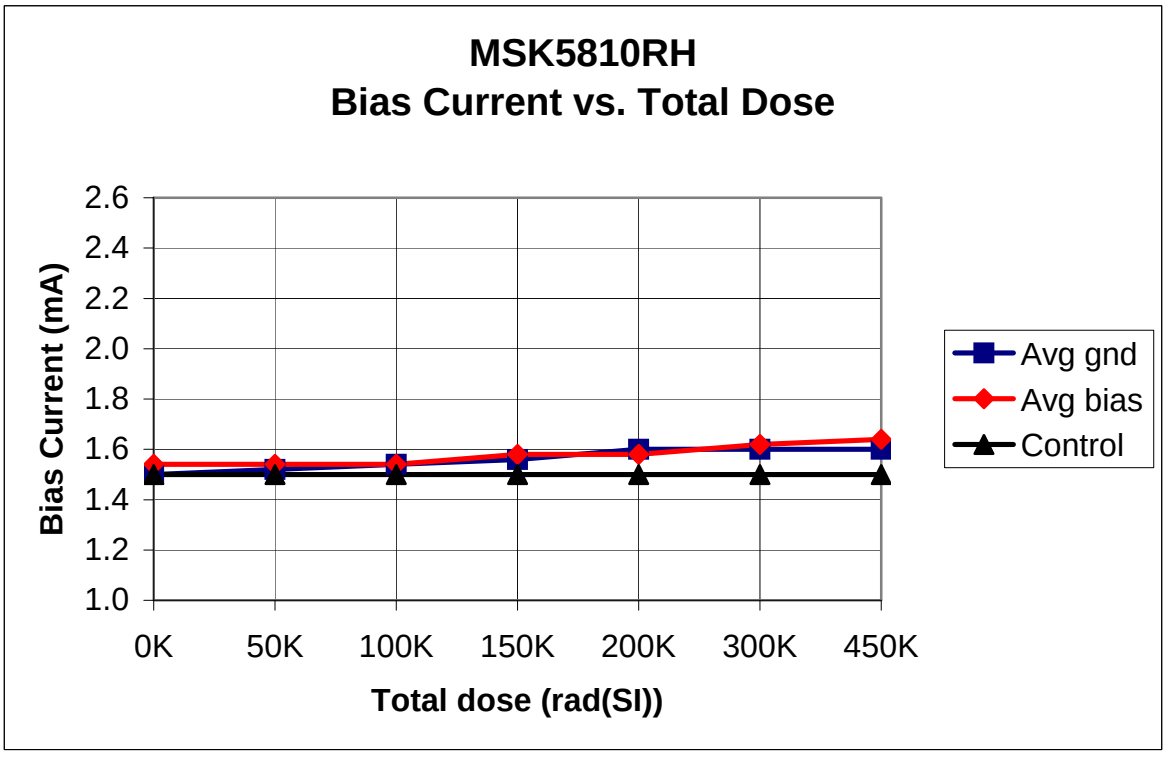
Biased S/N – 0276, 0277, 0278, 0279, 0280

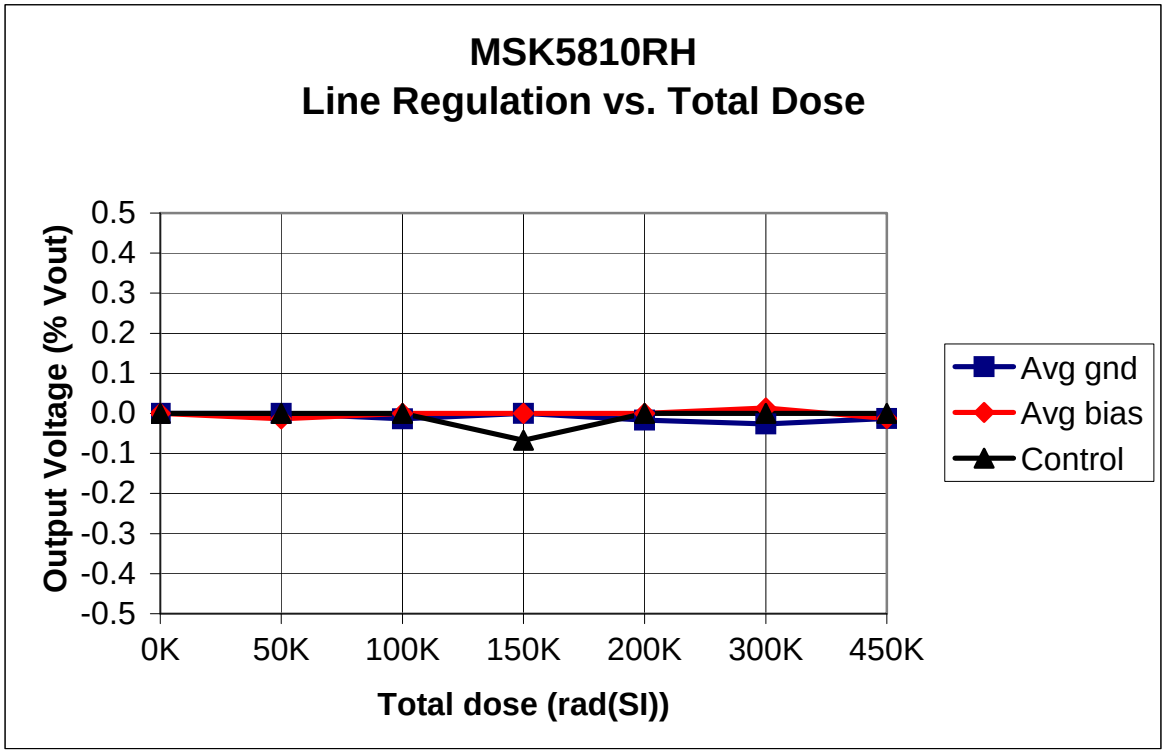
Unbiased S/N – 0281, 0282, 0283, 0284, 0285

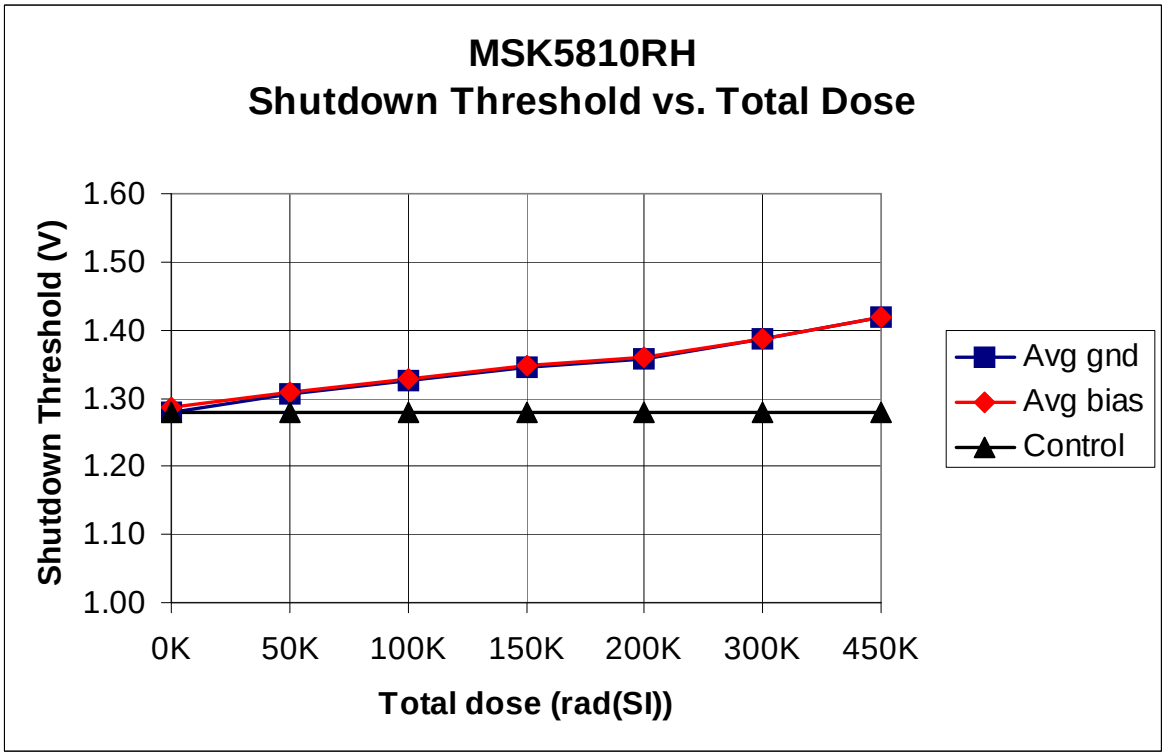
Table 1

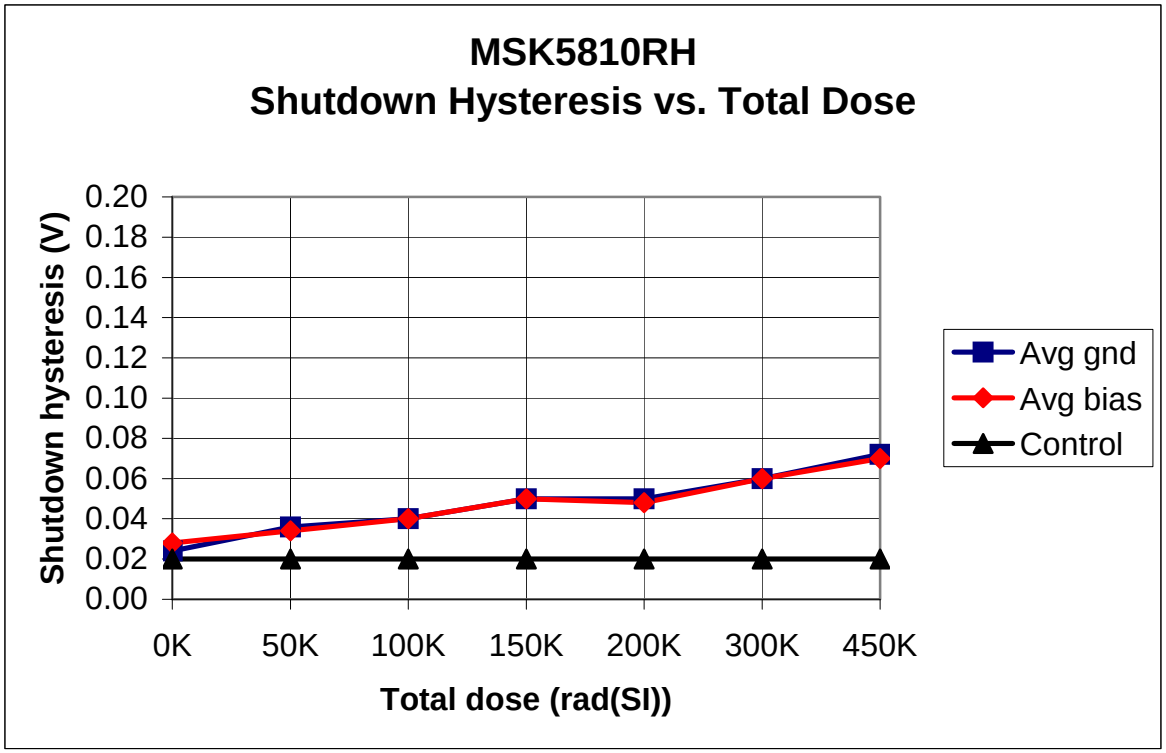
Dose Time, Incremental Dose and Total Cumulative Dose

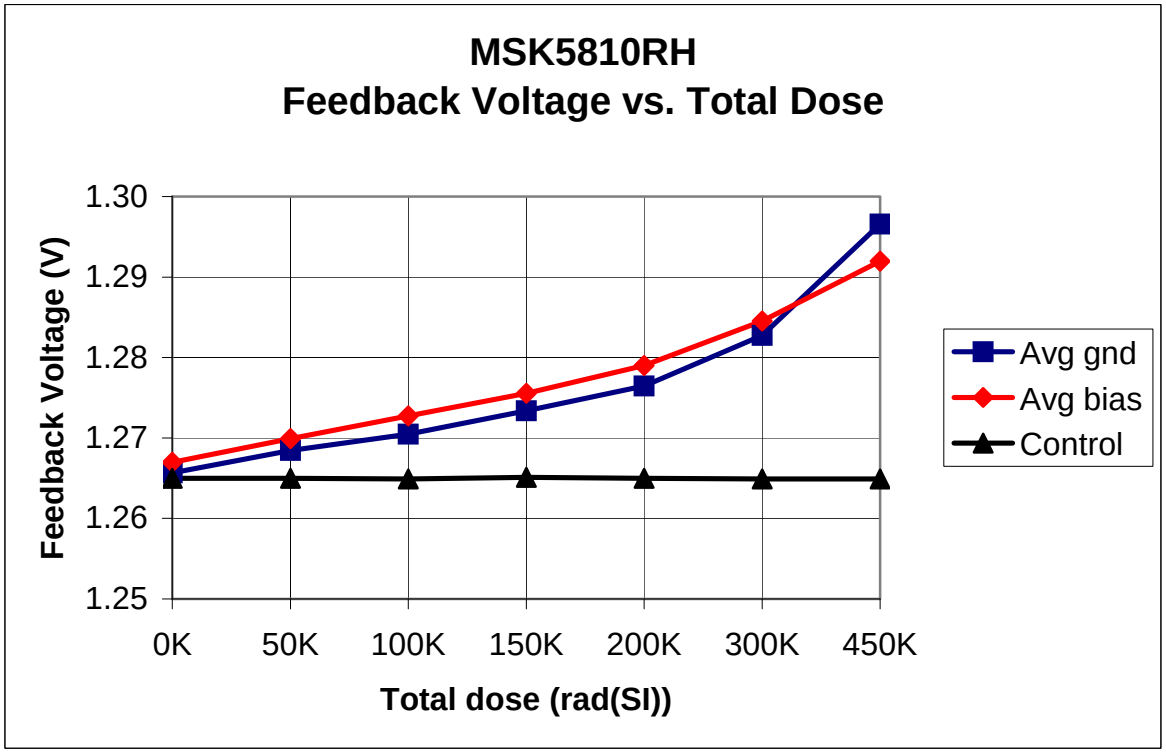

MSK5810RH
Quiescent Current vs. Total Dose
Quiescent Current (mA)
20.0
18.0
16.0
14.0
12.0
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control

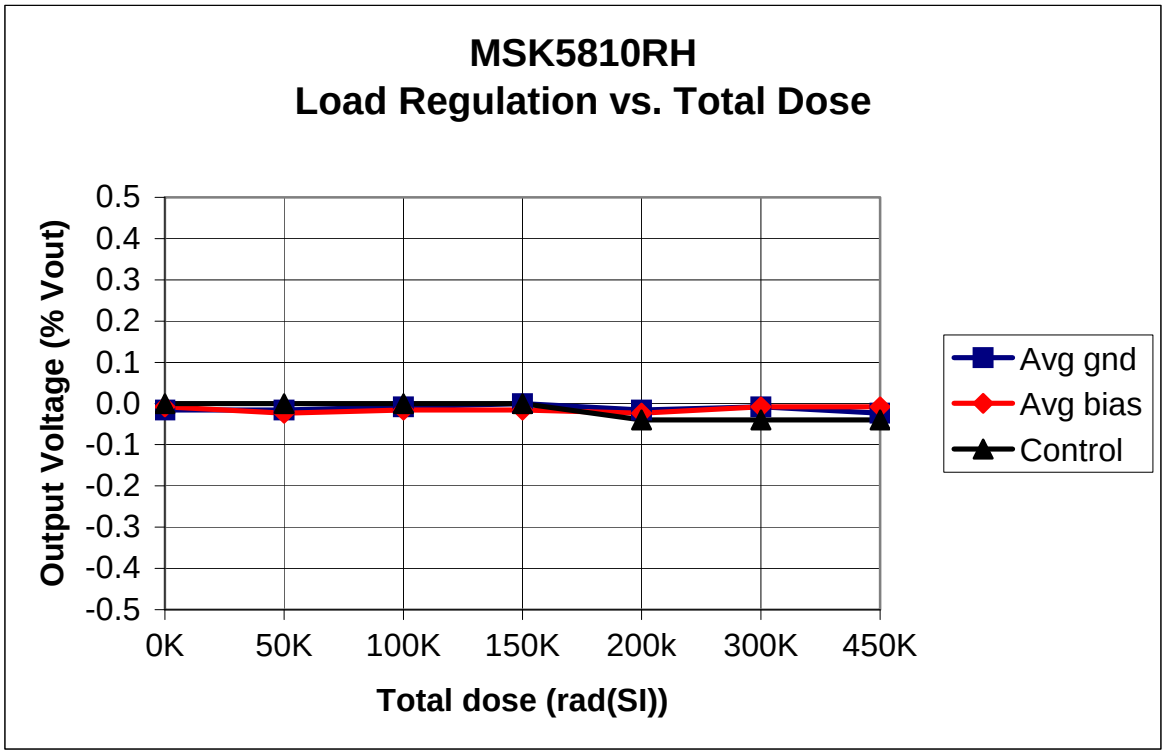

MSK5810RH
Bias Current vs. Total Dose
Bias Current (mA)
2.6
2.4
2.2
2.0
1.8
1.6
1.4
1.2
1.0
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control

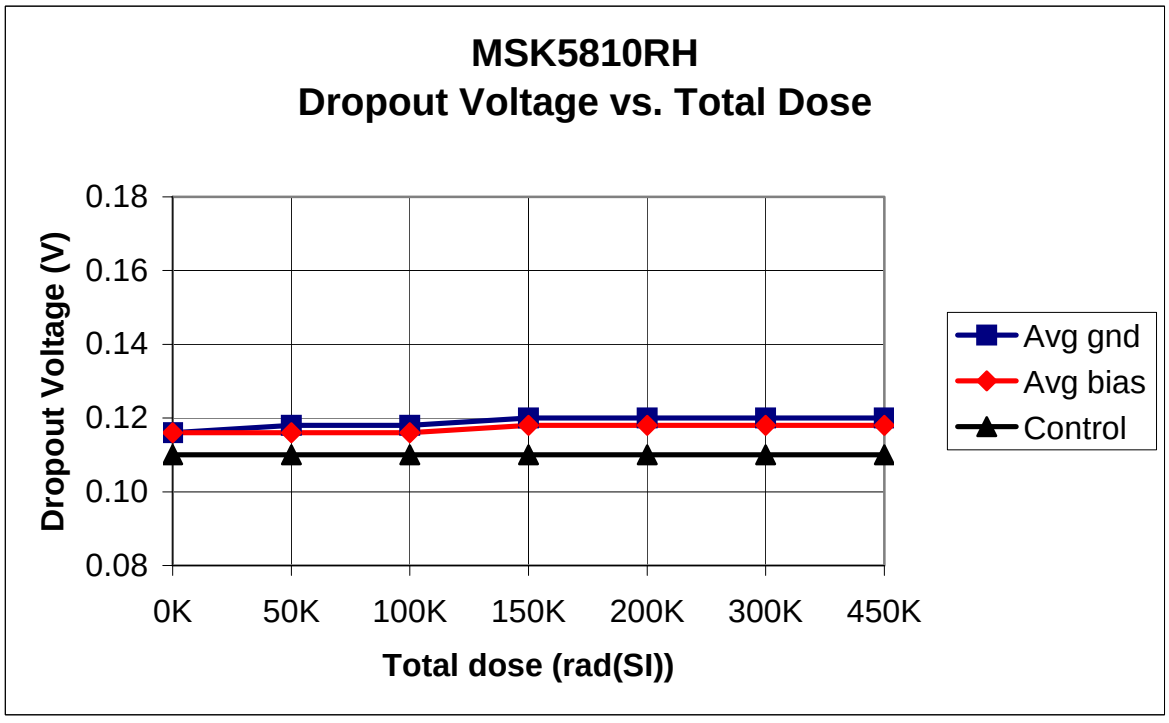

MSK5810RH
Line Regulation vs. Total Dose
Output Voltage (% Vout)
0.5
0.4
0.3
0.2
0.1
0.0
-0.1
-0.2
-0.3
-0.4
-0.5
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control

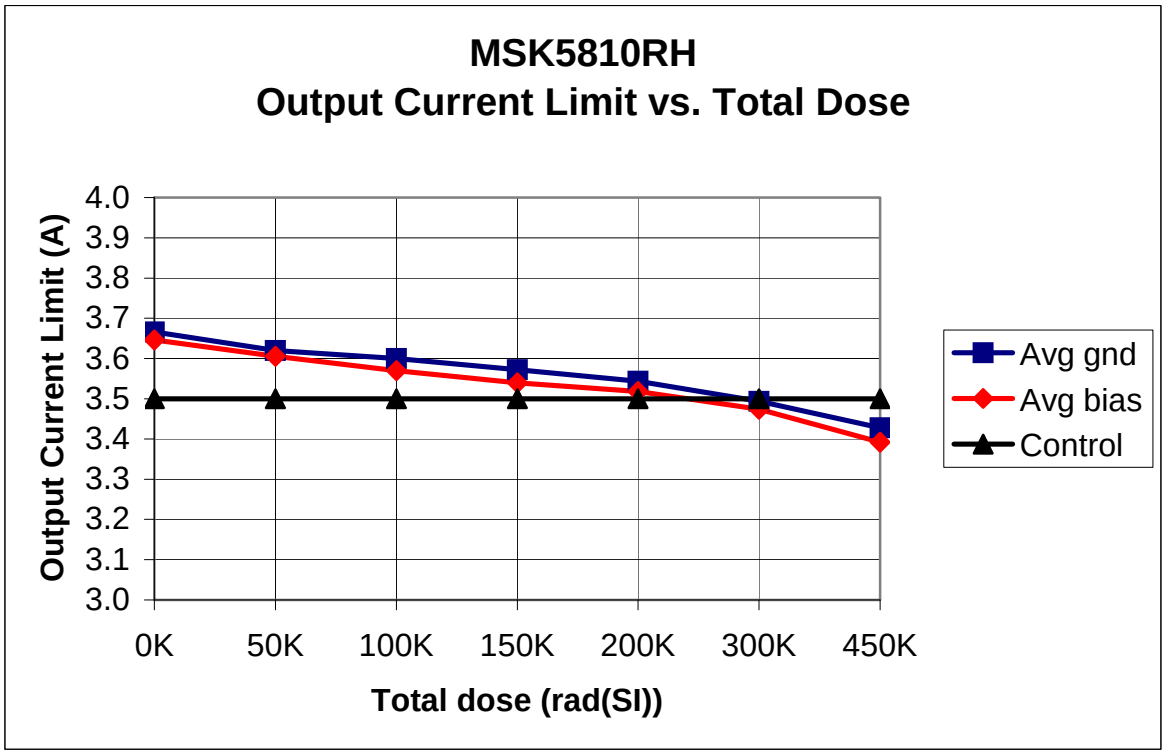

MSK5810RH
Shutdown Threshold vs. Total Dose
Shutdown Threshold (V)
1.60
1.50
1.40
1.30
1.20
1.10
1.00
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control


MSK5810RH
Shutdown Hysteresis vs. Total Dose
Shutdown hysteresis (V)
0.20
0.18
0.16
0.14
0.12
0.10
0.08
0.06
0.04
0.02
0.00
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(SI))
Avg gnd
Avg bias
Control


MSK5810RH
Feedback Voltage vs. Total Dose
Feedback Voltage (V)
1.30
1.29
1.28
1.27
1.26
1.25
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(SI))
Avg gnd
Avg bias
Control


MSK5810RH
Load Regulation vs. Total Dose
Output Voltage (% Vout)
0.5
0.4
0.3
0.2
0.1
0.0
-0.1
-0.2
-0.3
-0.4
-0.5
0K
50K
100K
150K
200k
300K
450K
Total dose (rad(SI))
Avg gnd
Avg bias
Control


MSK5810RH
Dropout Voltage vs. Total Dose
Dropout Voltage (V)
0.18
0.16
0.14
0.12
0.10
0.08
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(SI))
Avg gnd
Avg bias
Control


MSK5810RH
Output Current Limit vs. Total Dose
Output Current Limit (A)
4.0
3.9
3.8
3.7
3.6
3.5
3.4
3.3
3.2
3.1
3.0
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control

Total Dose Radiation Test Report

MSK 5810 RH
(MSK5800RH, MSK5820RH, MSK5821RH, MSK5822RH)
RAD Hard Ultra Low Dropout
Adjustable Positive Linear Regulator

November 25, 2008 (First Test)
Updated on December 24, 2008
March 26, 2009 (Second Test)

M. Bilecki
P. Musil

M.S. Kennedy Corporation
Liverpool, NY

I. Introduction:

The total dose radiation test plan for the MSK 5810 RH series was developed to qualify the devices as RAD Hard to 300 KRAD (Si). The testing was performed beyond 300 KRAD (Si) to show trends in device performance as a function of total dose. The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the specified total dose level. The MSK5810RH, MSK5820RH, MSK5821RH, MSK5822RH, and the MSK5800RH all use the same active components. The data in this report is from direct measurement of the MSK5810RH response to irradiation but it is indicative of the response of all five device types and is applicable to all five types.

MIL-STD-883 Method 1019.7 and ASTM F1892-06 were used as guidelines in the development and implementation of the total dose test plan for the MSK 5810RH.

II. Radiation Source:

Total dose was performed at the University of Massachusetts, Lowell, using a cobalt 60 radiation source. The dose rate was determined to be 184 Rads(Si)/sec. The total dose schedule can be found in Table I.

III. Test Setup:

All test samples were subjected to Group A Electrical Test at 25°C in accordance with the device data sheet. In addition, all devices received 320 hours of burn-in per MIL-STD-883 Method 1015. For test platform verification, one control device was tested at 25°C. Ten devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

The devices were vertically aligned with the radiation source and enclosed in a lead/aluminum container during irradiation. Five devices were kept under bias during irradiation. Maximum recommended operating voltage of +7.5V was used for the bias condition. Five devices had all leads grounded during irradiation for the unbiased condition.

After each irradiation the device leads were shorted together and transported to the MSK automatic electrical test platform and tested IAW MSK device data sheet. Testing was performed on irradiated devices, as well as the control device, at each total dose level. Electrical tests were completed within one hour of irradiation. Devices were subjected to subsequent radiation doses within two hours of removal from the radiation field.

IV. Data:

All performance curves are averaged from the test results of the biased and unbiased devices, respectively. If required, full test data can be obtained by contacting M.S. Kennedy Corporation.

V. Summary:

Based on the test data recorded during radiation testing and statistical analysis, the MSK5810RH qualified as a 300 KRAD (Si) radiation hardened device. Feedback Voltage, Shutdown Threshold, and Output Current Limit exhibited the most significant shift due to irradiation, however all performance curves stayed within specification up to 450 KRAD (Si) TID.

MSK 5810RH Biased/Unbiased Dose Rate Schedule

Dosimetry Equipment
Bruker Biospin # 0141

Irradiation Date
03/17/09

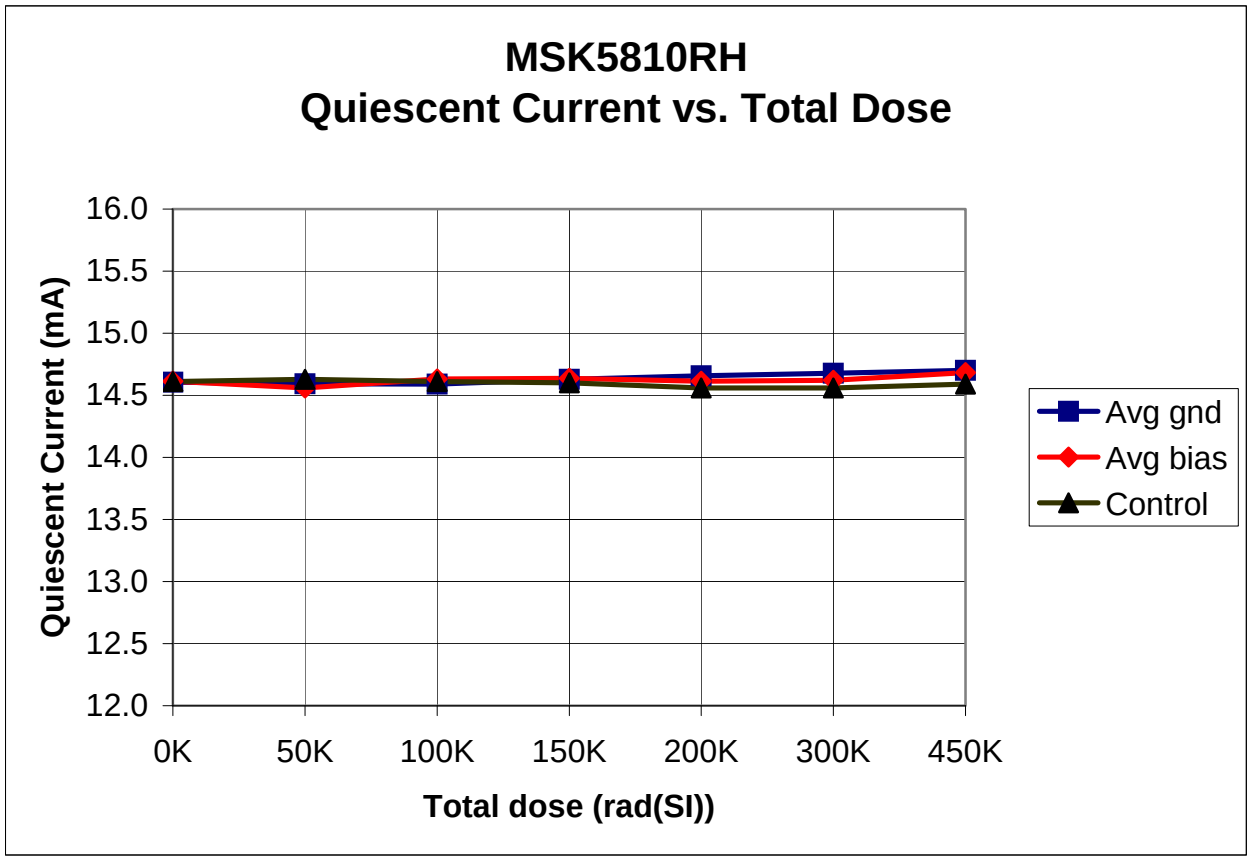
Exposure Length (min:sec)	Incremental Dose rads(Si)	Cumulative Dose rads(Si)
4:40	51,520	51,520
4:40	51,520	103,040
4:40	51,520	154,560
4:40	51,520	206,080
9:20	103,040	309,120
14:00	154,560	463,680

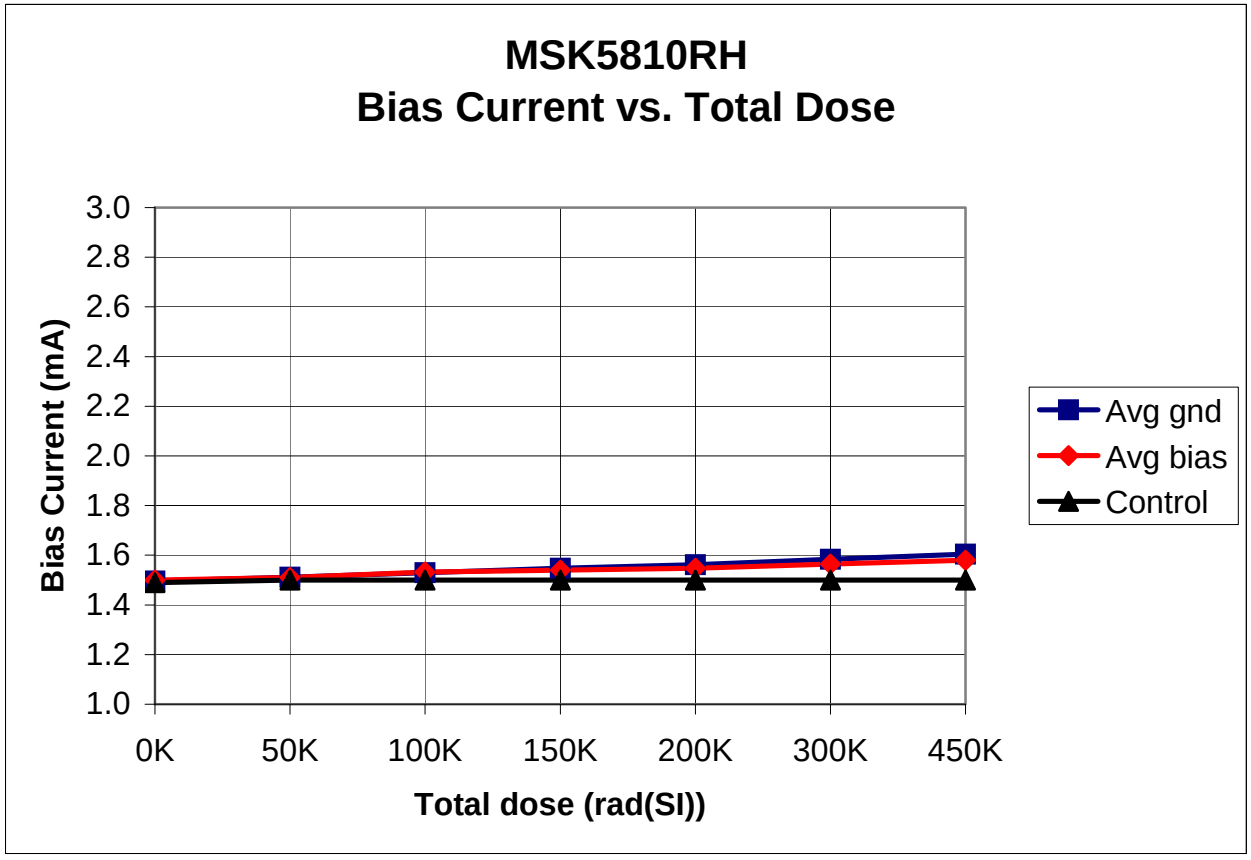
Biased S/N – 0054, 0055, 0056, 0057, 0058

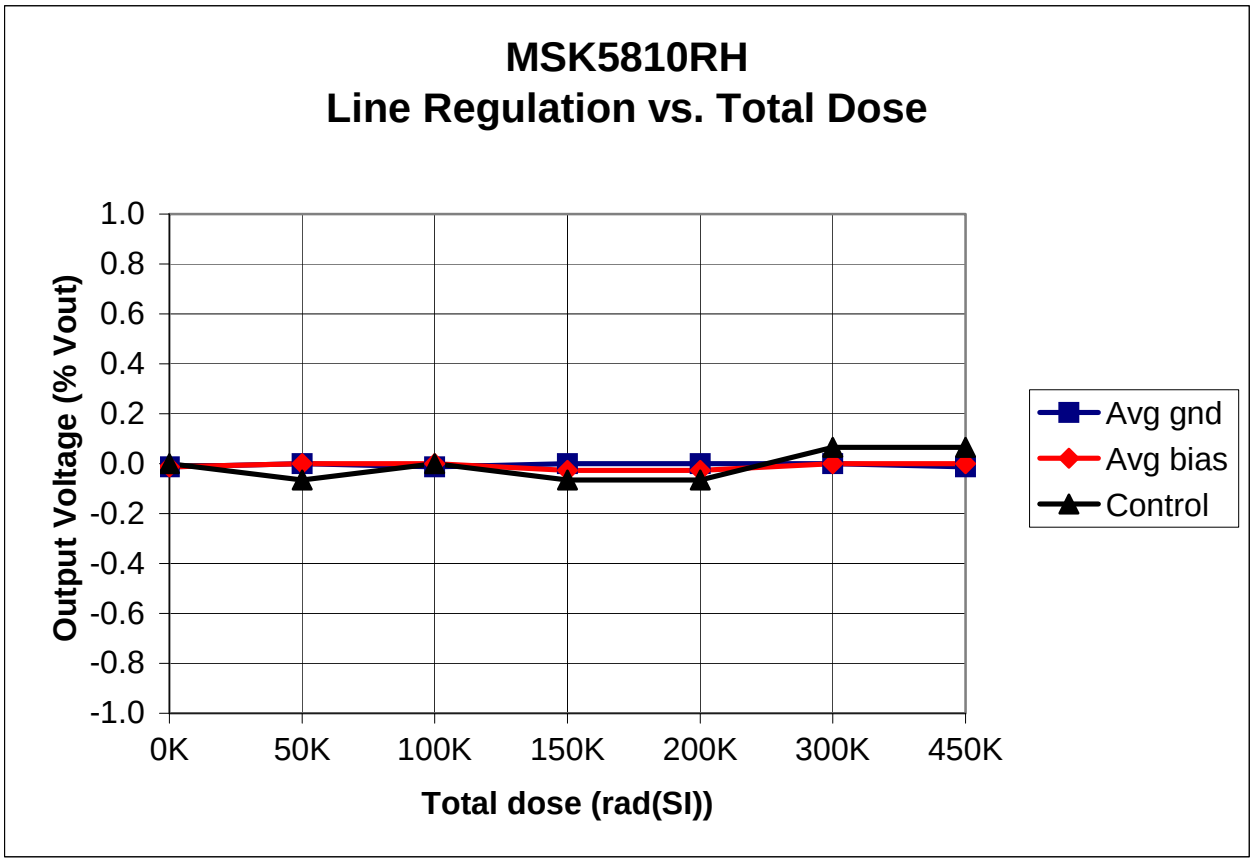
Unbiased S/N – 0059, 0060, 0061, 0062, 0063

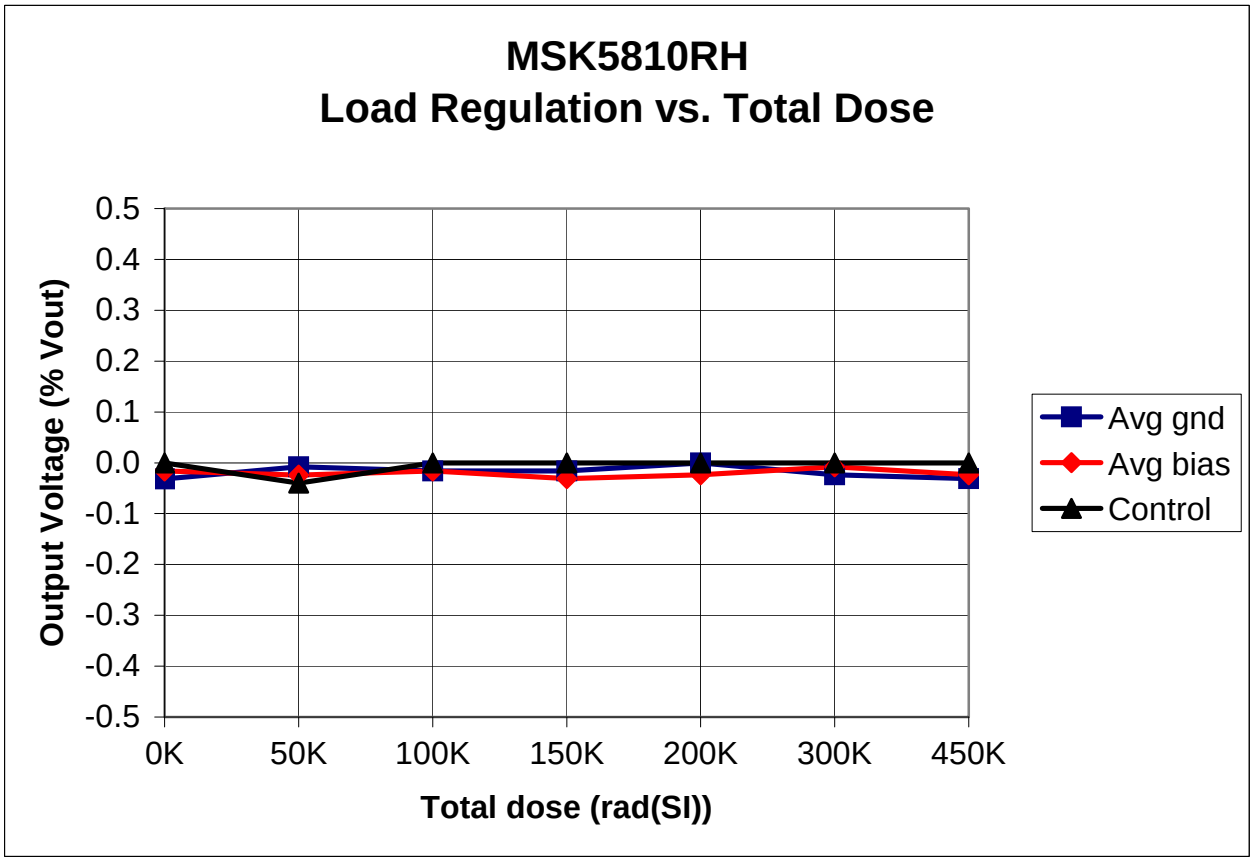
Table 1

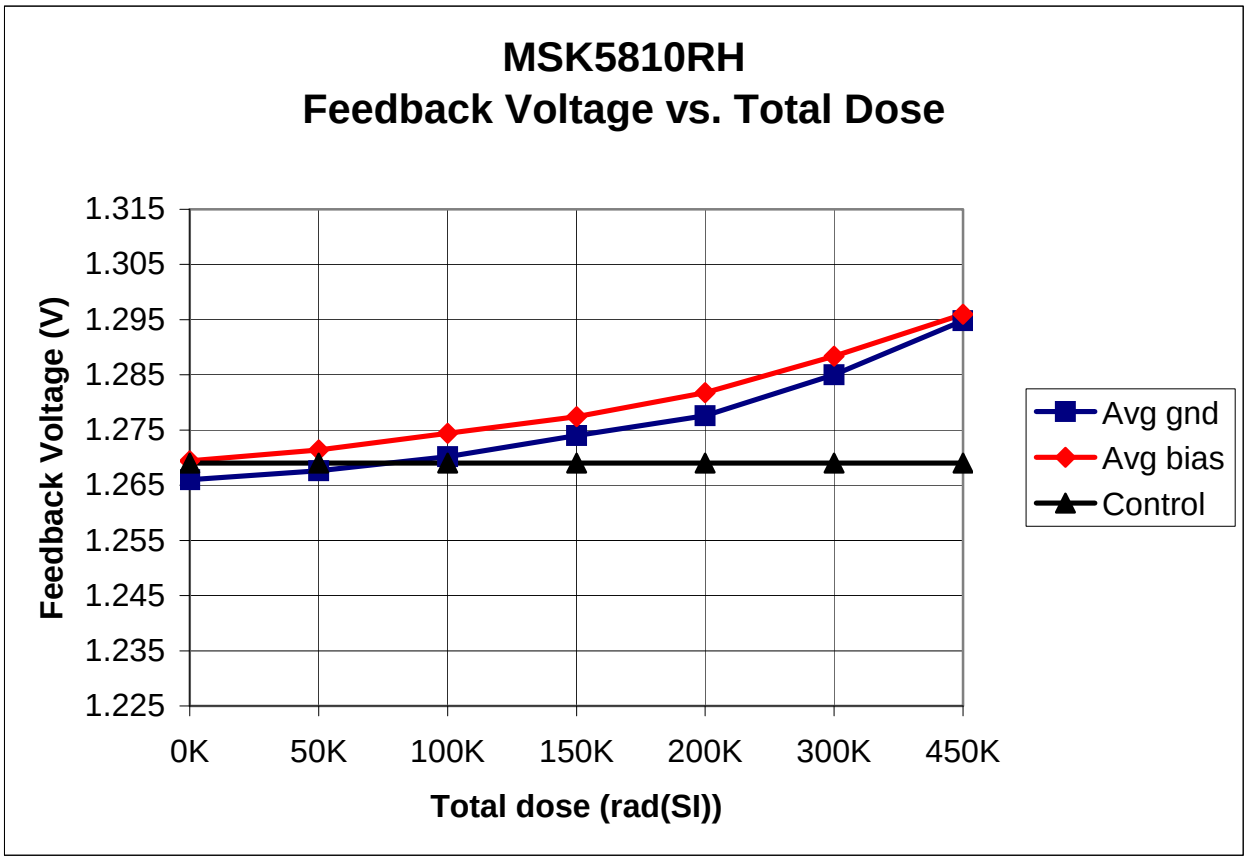
Dose Time, Incremental Dose and Total Cumulative Dose

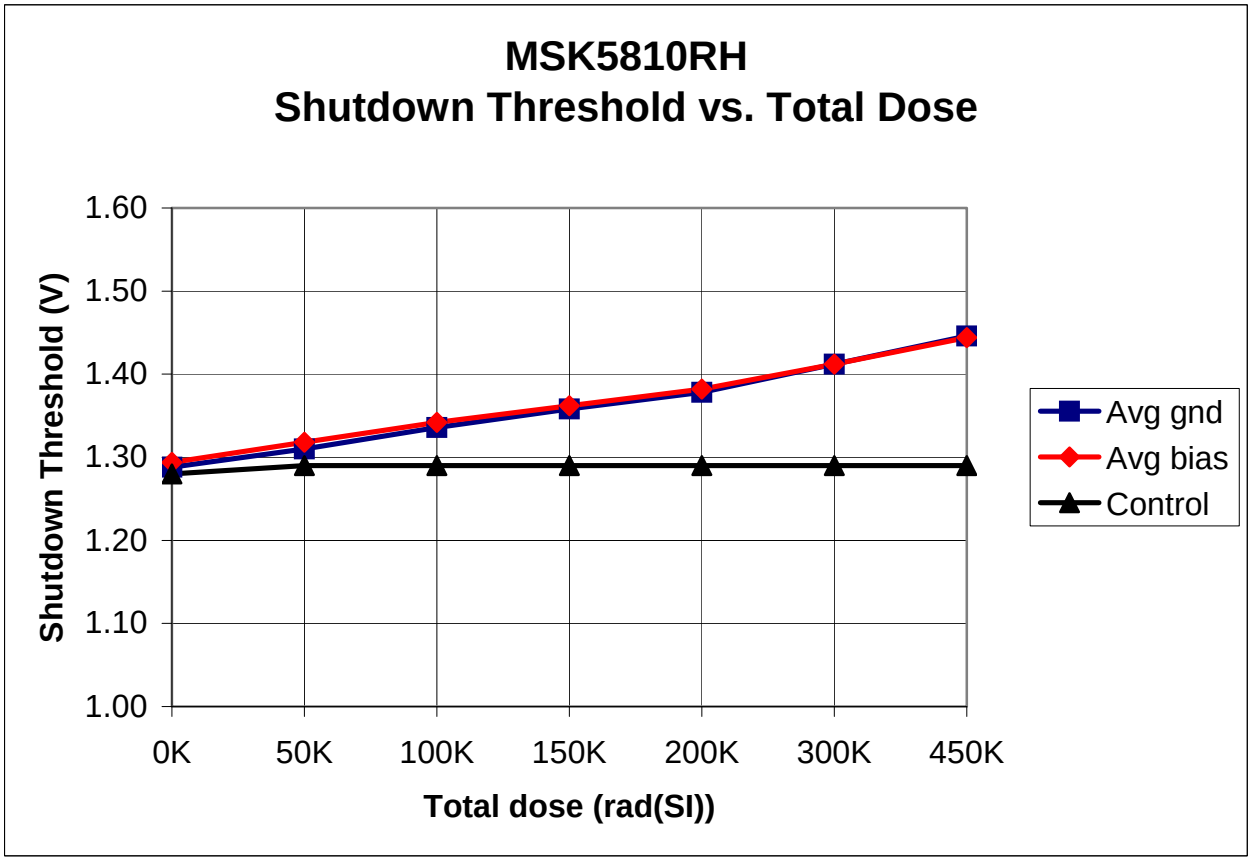

MSK5810RH
Quiescent Current vs. Total Dose
Quiescent Current (mA)
16.0
15.5
15.0
14.5
14.0
13.5
13.0
12.5
12.0
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(SI))
Avg gnd
Avg bias
Control

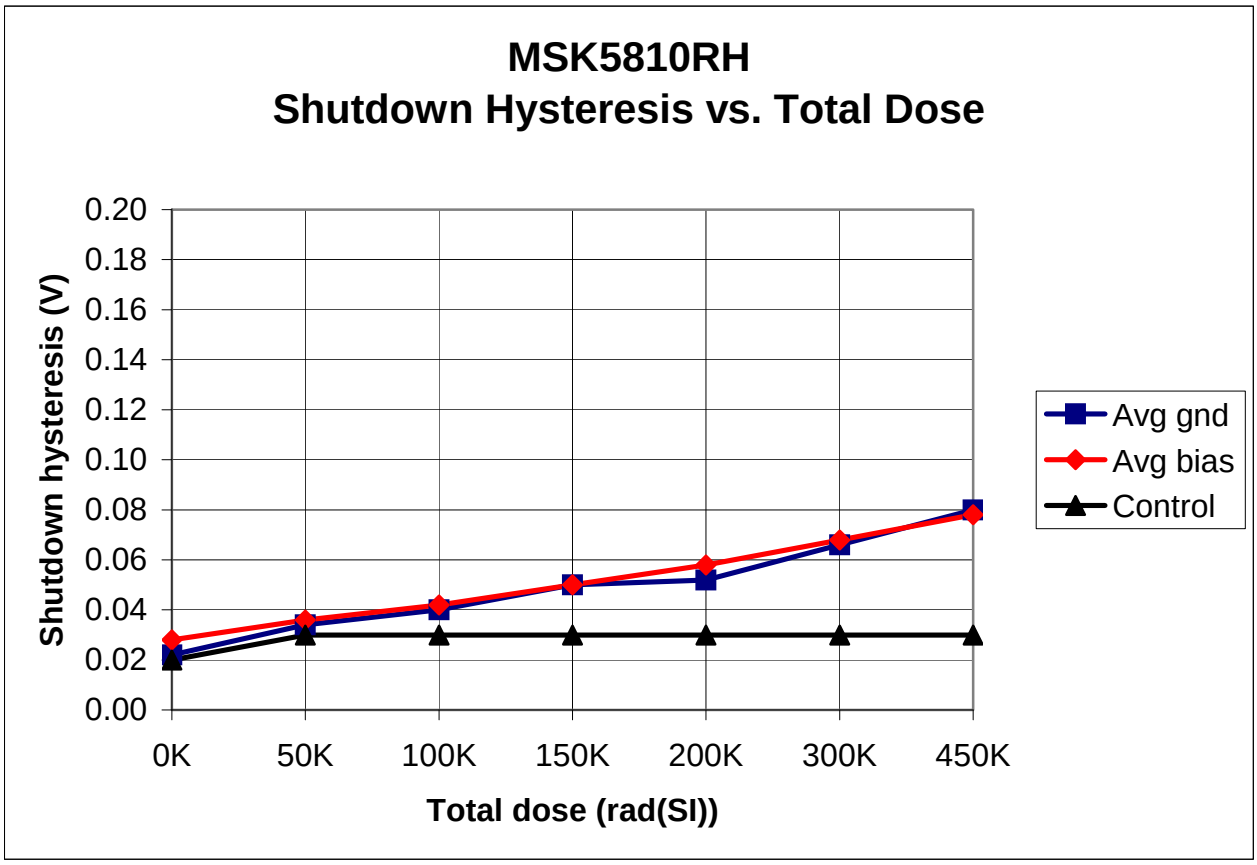

MSK5810RH
Bias Current vs. Total Dose
Bias Current (mA)
3.0
2.8
2.6
2.4
2.2
2.0
1.8
1.6
1.4
1.2
1.0
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(SI))
Avg gnd
Avg bias
Control

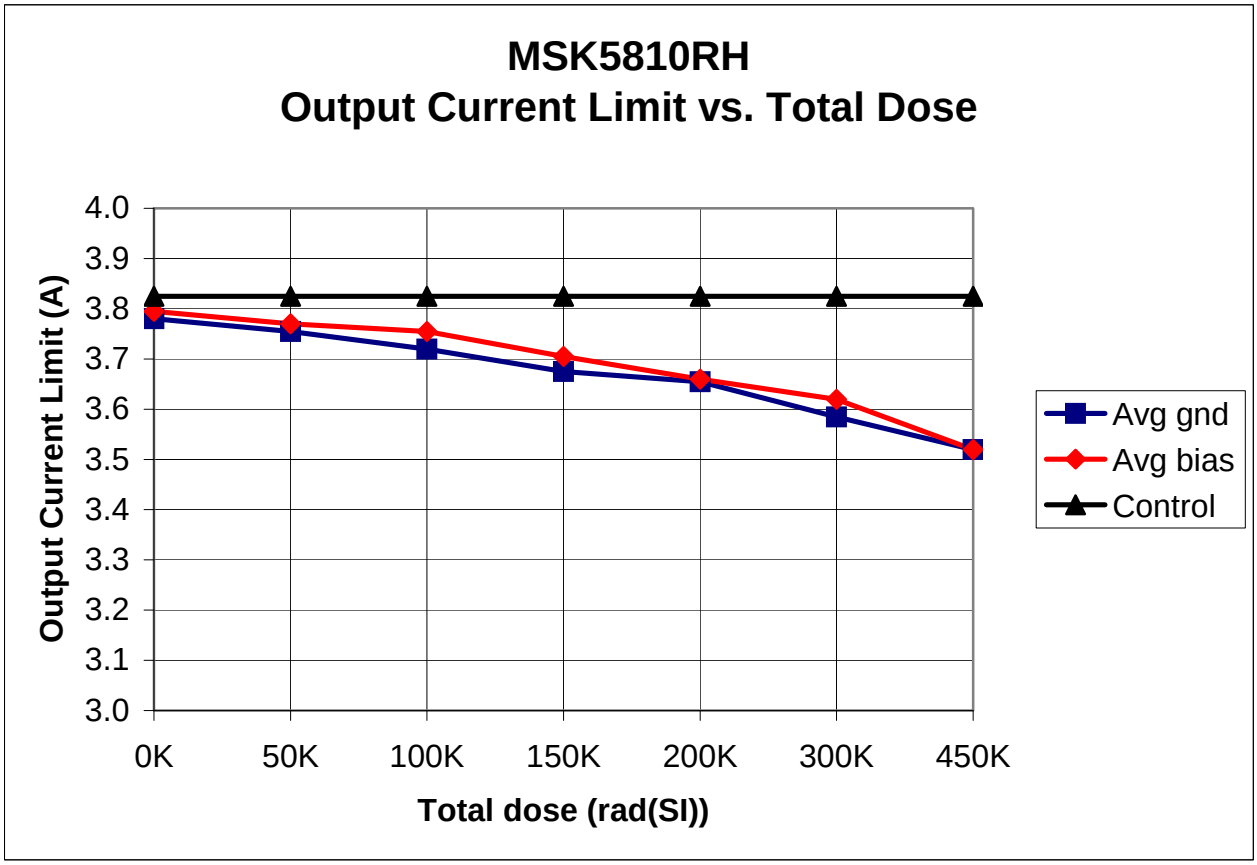

MSK5810RH
Line Regulation vs. Total Dose
Output Voltage (% Vout)
1.0
0.8
0.6
0.4
0.2
0.0
-0.2
-0.4
-0.6
-0.8
-1.0
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(SI))
Avg gnd
Avg bias
Control

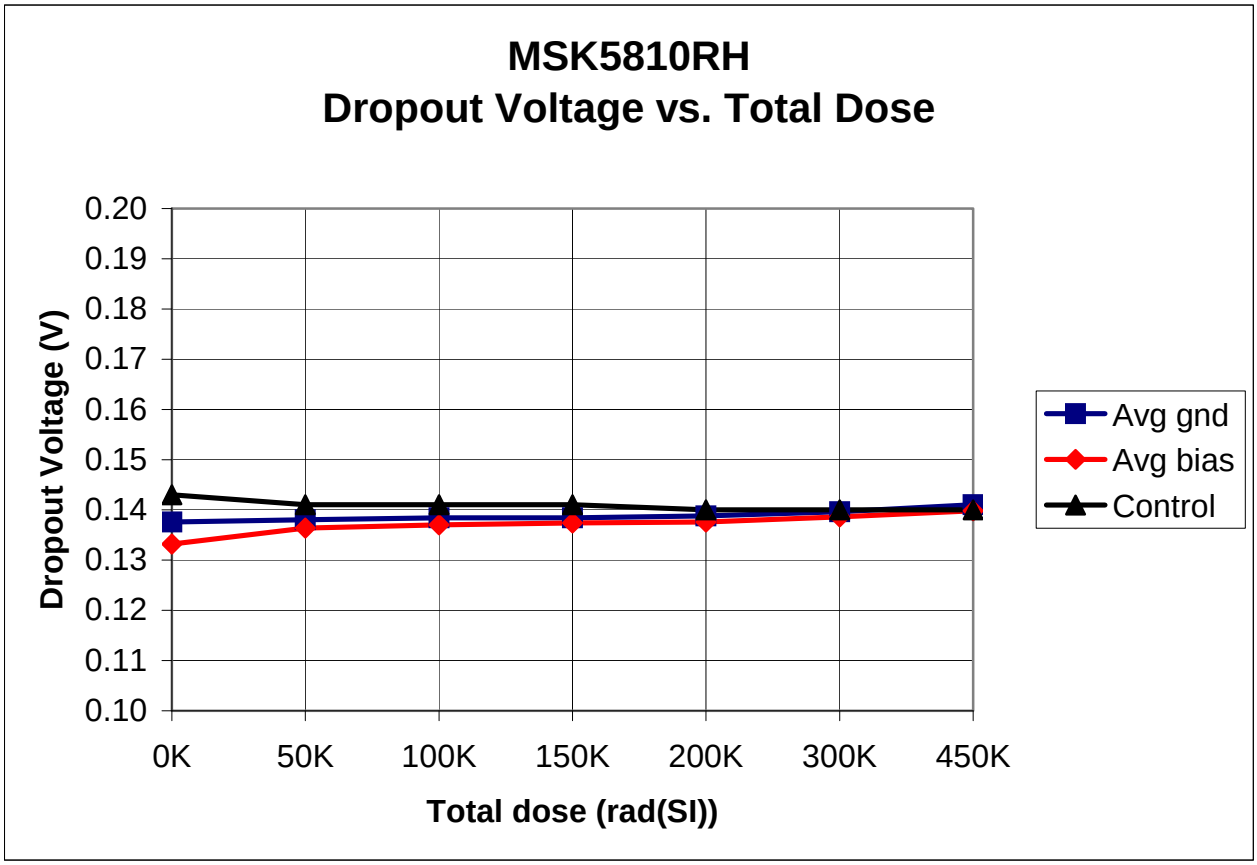

MSK5810RH
Load Regulation vs. Total Dose
Output Voltage (% Vout)
0.5
0.4
0.3
0.2
0.1
0.0
-0.1
-0.2
-0.3
-0.4
-0.5
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(SI))
Avg gnd
Avg bias
Control


MSK5810RH
Feedback Voltage vs. Total Dose
Feedback Voltage (V)
1.315
1.305
1.295
1.285
1.275
1.265
1.255
1.245
1.235
1.225
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(SI))
Avg gnd
Avg bias
Control


MSK5810RH
Shutdown Threshold vs. Total Dose
Shutdown Threshold (V)
1.60
1.50
1.40
1.30
1.20
1.10
1.00
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(SI))
Avg gnd
Avg bias
Control


MSK5810RH
Shutdown Hysteresis vs. Total Dose
Shutdown hysteresis (V)
0.20
0.18
0.16
0.14
0.12
0.10
0.08
0.06
0.04
0.02
0.00
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control


MSK5810RH
Output Current Limit vs. Total Dose
Output Current Limit (A)
4.0
3.9
3.8
3.7
3.6
3.5
3.4
3.3
3.2
3.1
3.0
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control


MSK5810RH
Dropout Voltage vs. Total Dose
Dropout Voltage (V)
0.20
0.19
0.18
0.17
0.16
0.15
0.14
0.13
0.12
0.11
0.10
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(SI))
Avg gnd
Avg bias
Control

Total Dose Radiation Test Report

MSK 5822 RH

RAD Hard Ultra Low Dropout
Adjustable Positive Linear Regulator

March 21, 2009

J. Douglas
P. Musil

M.S. Kennedy Corporation
Liverpool, NY

I. Introduction:

The total dose radiation test plan for the MSK 5822 RH series was developed to qualify the devices as RAD Hard to 300 KRAD (Si). The testing was performed beyond 300 KRAD (Si) to show trends in device performance as a function of total dose. The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the specified total dose level.

MIL-STD-883 Method 1019.7 and ASTM F1892-06 were used as guidelines in the development and implementation of the total dose test plan for the MSK 5822 RH.

II. Radiation Source:

Total dose was performed at the University of Massachusetts, Lowell, using a cobalt 60 radiation source. The dose rate was determined to be 179 Rads(Si)/sec. The total dose schedule can be found in Table I.

III. Test Setup:

All test samples were subjected to Group A Electrical Test at 25°C in accordance with the device data sheet. In addition, all devices received 320 hours of burn-in per MIL-STD-883 Method 1015. For test platform verification, one control device was tested at 25°C. Ten devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

The devices were vertically aligned with the radiation source and enclosed in a lead/aluminum container during irradiation. Five devices were kept under bias during irradiation. Maximum recommended operating voltage of +7.5V was used for the bias condition. Five devices had all leads grounded during irradiation for the unbiased condition.

After each irradiation the device leads were shorted together and transported to the MSK automatic electrical test platform and tested IAW MSK device data sheet. Testing was performed on irradiated devices, as well as the control device, at each total dose level. Electrical tests were completed within one hour of irradiation. Devices were subjected to subsequent radiation doses within two hours of removal from the radiation field.

IV. Data:

All performance curves are averaged from the test results of the biased and unbiased devices, respectively. If required, full test data can be obtained by contacting M.S. Kennedy Corporation.

V. Summary:

Based on the test data recorded during radiation testing, the MSK5822RH qualified as a 300 KRAD (Si) radiation hardened device. Output Voltage, Output Current Limit and Drop Out Voltage exhibited the most significant shift due to irradiation, however all performance curves stayed within specification up to 450 KRAD (Si) TID.

MSK 5822RH Biased/Unbiased Dose Rate Schedule

Dosimetry Equipment
Bruker Biospin # 0141

Irradiation Date
03/17/09

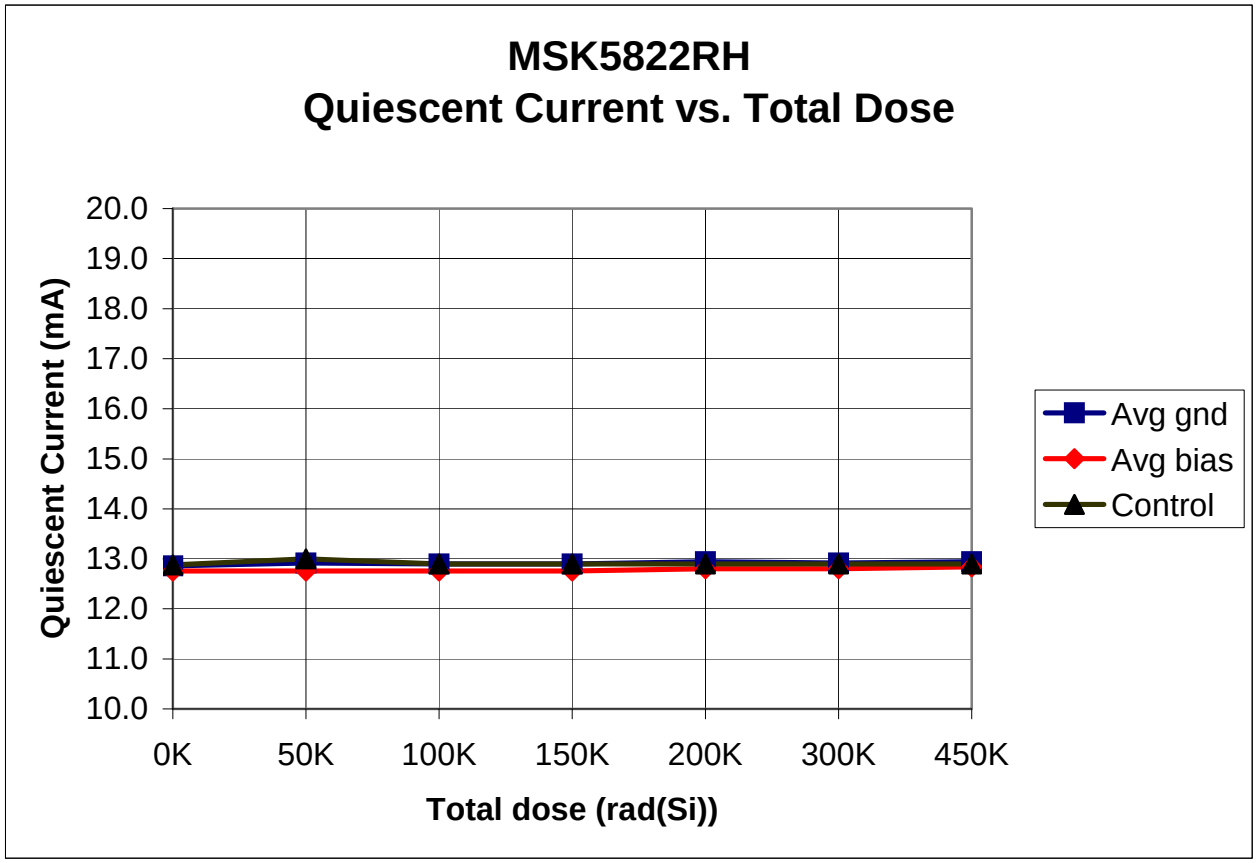
Exposure Length (min:sec)	Incremental Dose rads(Si)	Cumulative Dose rads(Si)
4:48	51,552	51,552
4:48	51,552	103,104
4:48	51,552	154,656
4:48	51,552	206,208
9:36	103,104	309,312
14:22	154,298	463,610

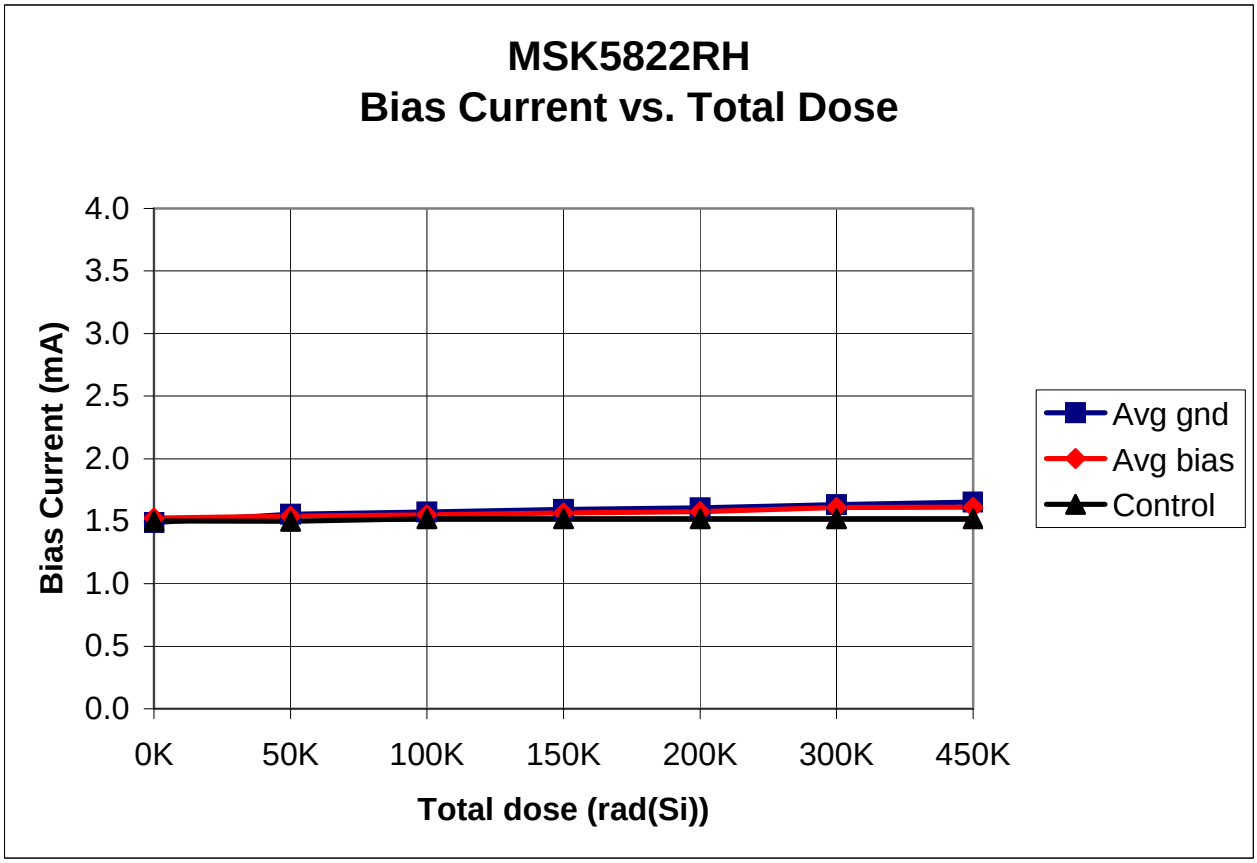
Biased S/N – 5874,5875,5876,5877,5878

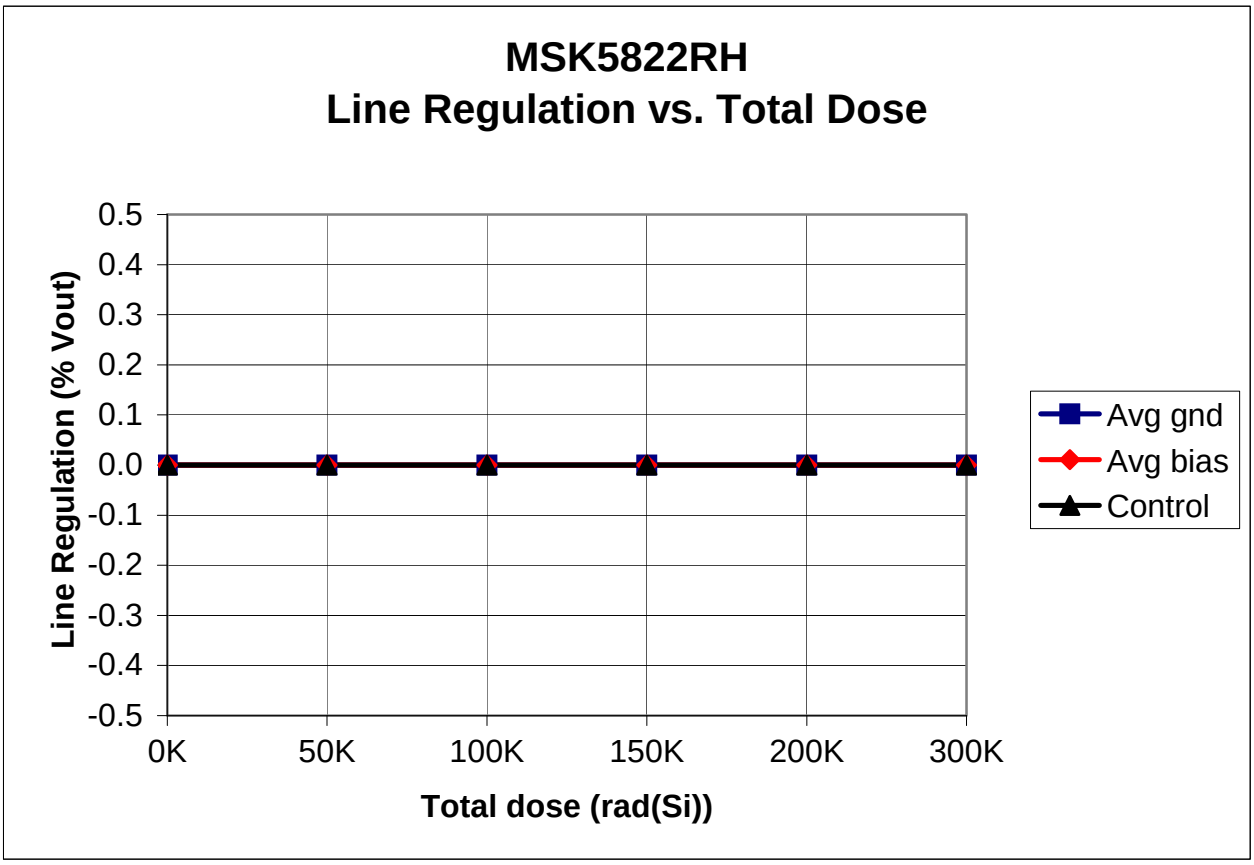
Unbiased S/N – 5879,5880,5881,5883,5885

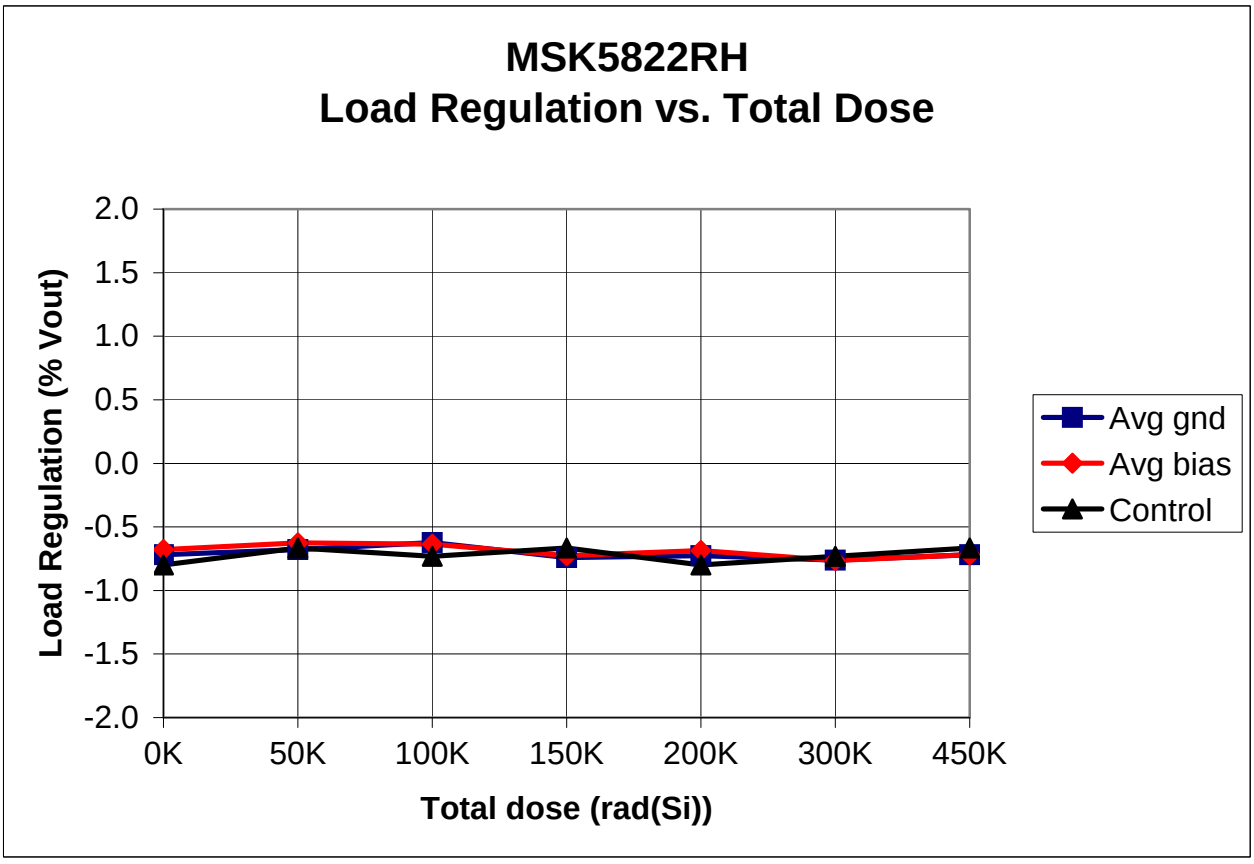
Table 1

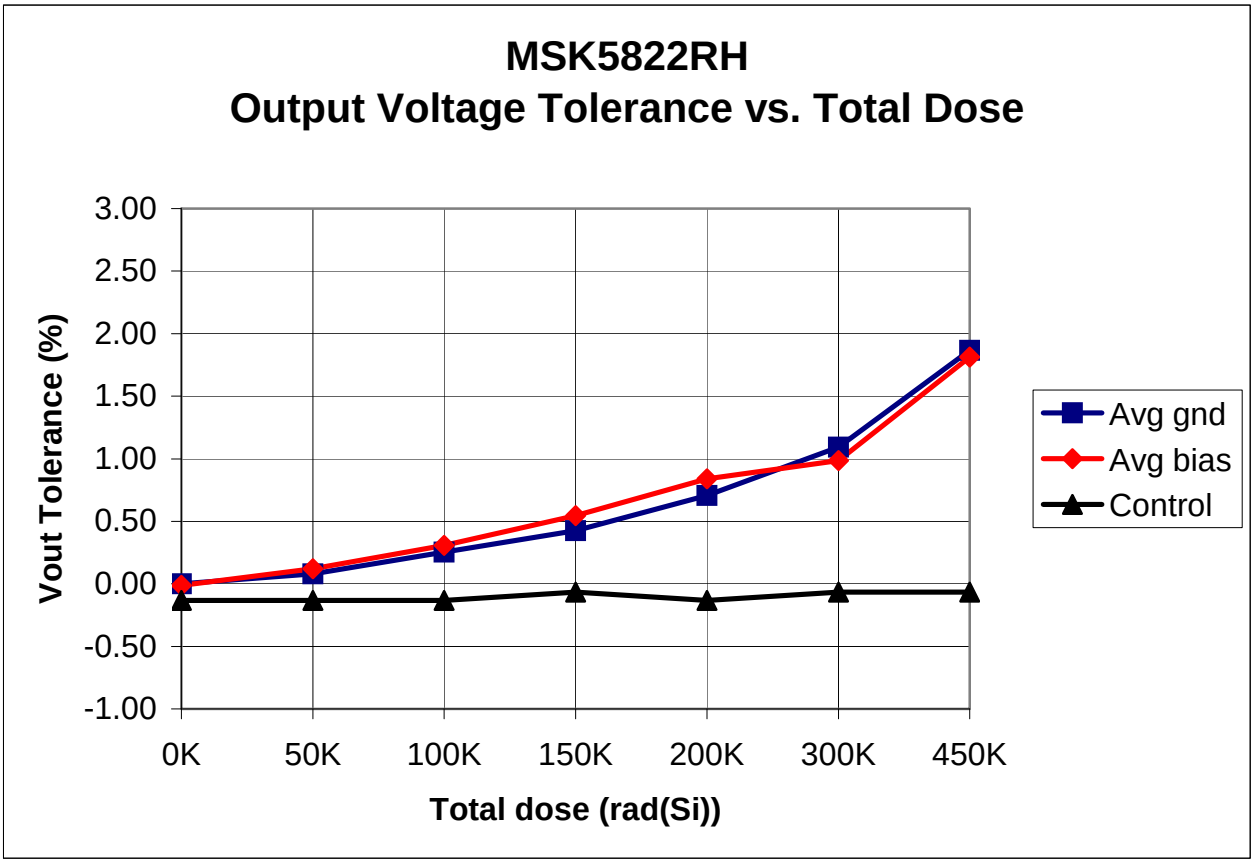
Dose Time, Incremental Dose and Total Cumulative Dose

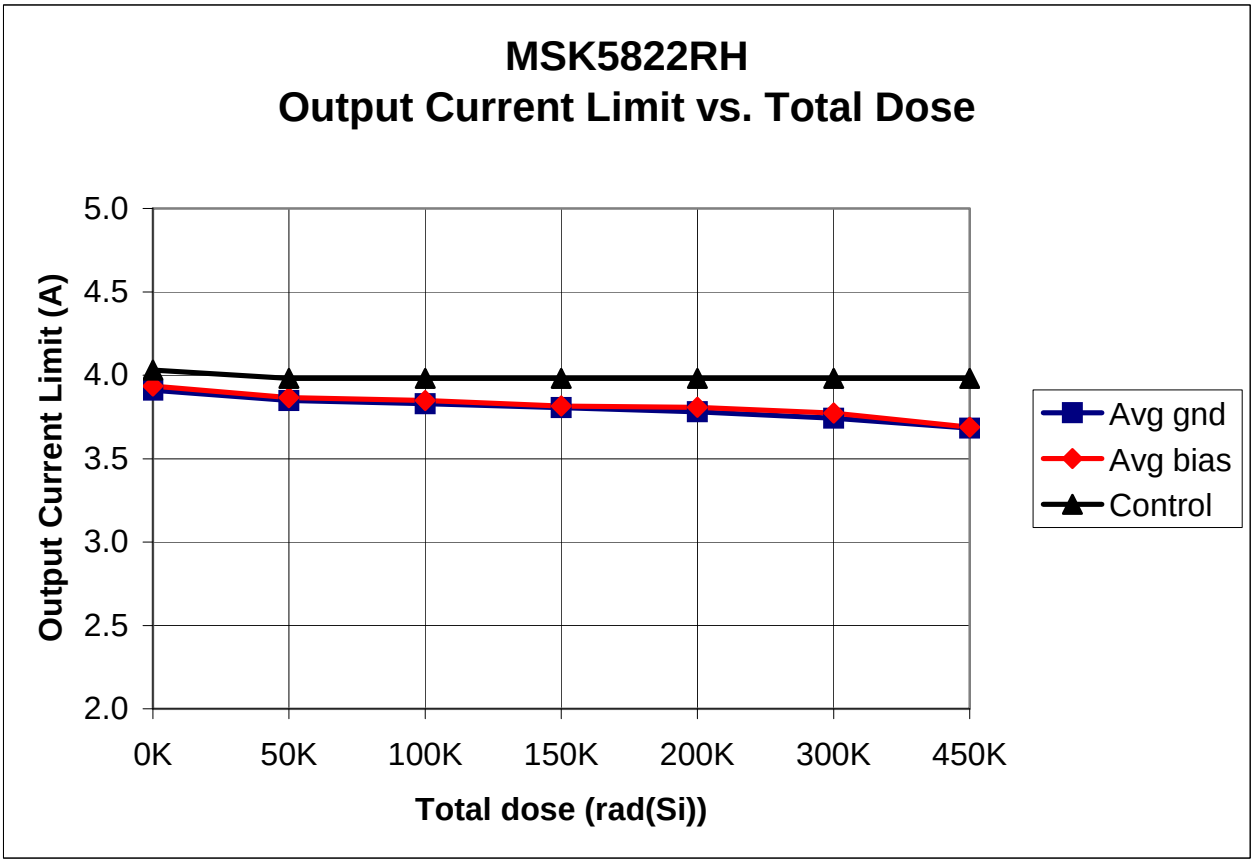

MSK5822RH
Quiescent Current vs. Total Dose
Quiescent Current (mA)
20.0
19.0
18.0
17.0
16.0
15.0
14.0
13.0
12.0
11.0
10.0
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control

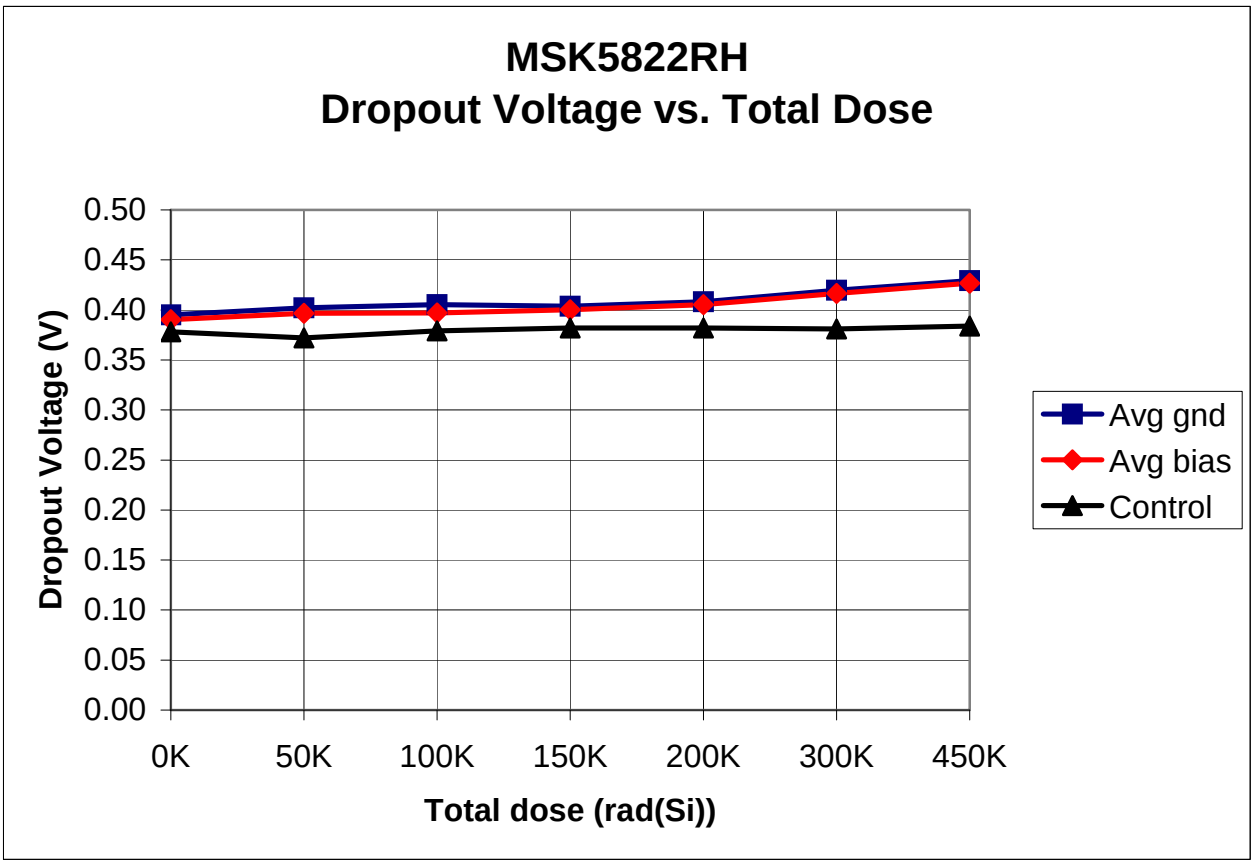

MSK5822RH
Bias Current vs. Total Dose
Bias Current (mA)
4.0
3.5
3.0
2.5
2.0
1.5
1.0
0.5
0.0
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control


MSK5822RH
Line Regulation vs. Total Dose
Line Regulation (% Vout)
0.5
0.4
0.3
0.2
0.1
0.0
-0.1
-0.2
-0.3
-0.4
-0.5
0K
50K
100K
150K
200K
300K
Total dose (rad(Si))
Avg gnd
Avg bias
Control


MSK5822RH
Load Regulation vs. Total Dose
Load Regulation (% Vout)
2.0
1.5
1.0
0.5
0.0
-0.5
-1.0
-1.5
-2.0
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control


MSK5822RH
Output Voltage Tolerance vs. Total Dose
Vout Tolerance (%)
3.00
2.50
2.00
1.50
1.00
0.50
0.00
-0.50
-1.00
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control


MSK5822RH
Output Current Limit vs. Total Dose
Output Current Limit (A)
5.0
4.5
4.0
3.5
3.0
2.5
2.0
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control


MSK5822RH
Dropout Voltage vs. Total Dose
Dropout Voltage (V)
0.50
0.45
0.40
0.35
0.30
0.25
0.20
0.15
0.10
0.05
0.00
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control

Total Dose Radiation Test Report

MSK 5810 RH
(MSK5800RH, MSK5820RH, MSK5821RH, MSK5822RH)
RAD Hard Ultra Low Dropout
Adjustable Positive Linear Regulator

November 25, 2008 (First Test)
Updated on December 24, 2008
March 26, 2009 (Second Test)

M. Bilecki
P. Musil

M.S. Kennedy Corporation
Liverpool, NY

I. Introduction:

The total dose radiation test plan for the MSK 5810 RH series was developed to qualify the devices as RAD Hard to 300 KRAD (Si). The testing was performed beyond 300 KRAD (Si) to show trends in device performance as a function of total dose. The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the specified total dose level. The MSK5810RH, MSK5820RH, MSK5821RH, MSK5822RH, and the MSK5800RH all use the same active components. The data in this report is from direct measurement of the MSK5810RH response to irradiation but it is indicative of the response of all five device types and is applicable to all five types.

MIL-STD-883 Method 1019.7 and ASTM F1892-06 were used as guidelines in the development and implementation of the total dose test plan for the MSK 5810RH.

II. Radiation Source:

Total dose was performed at the University of Massachusetts, Lowell, using a cobalt 60 radiation source. The dose rate was determined to be 184 Rads(Si)/sec. The total dose schedule can be found in Table I.

III. Test Setup:

All test samples were subjected to Group A Electrical Test at 25°C in accordance with the device data sheet. In addition, all devices received 320 hours of burn-in per MIL-STD-883 Method 1015. For test platform verification, one control device was tested at 25°C. Ten devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

The devices were vertically aligned with the radiation source and enclosed in a lead/aluminum container during irradiation. Five devices were kept under bias during irradiation. Maximum recommended operating voltage of +7.5V was used for the bias condition. Five devices had all leads grounded during irradiation for the unbiased condition.

After each irradiation the device leads were shorted together and transported to the MSK automatic electrical test platform and tested IAW MSK device data sheet. Testing was performed on irradiated devices, as well as the control device, at each total dose level. Electrical tests were completed within one hour of irradiation. Devices were subjected to subsequent radiation doses within two hours of removal from the radiation field.

IV. Data:

All performance curves are averaged from the test results of the biased and unbiased devices, respectively. If required, full test data can be obtained by contacting M.S. Kennedy Corporation.

V. Summary:

Based on the test data recorded during radiation testing and statistical analysis, the MSK5810RH qualified as a 300 KRAD (Si) radiation hardened device. Feedback Voltage, Shutdown Threshold, and Output Current Limit exhibited the most significant shift due to irradiation, however all performance curves stayed within specification up to 450 KRAD (Si) TID.

MSK 5810RH Biased/Unbiased Dose Rate Schedule

Dosimetry Equipment
Bruker Biospin # 0141

Irradiation Date
03/17/09

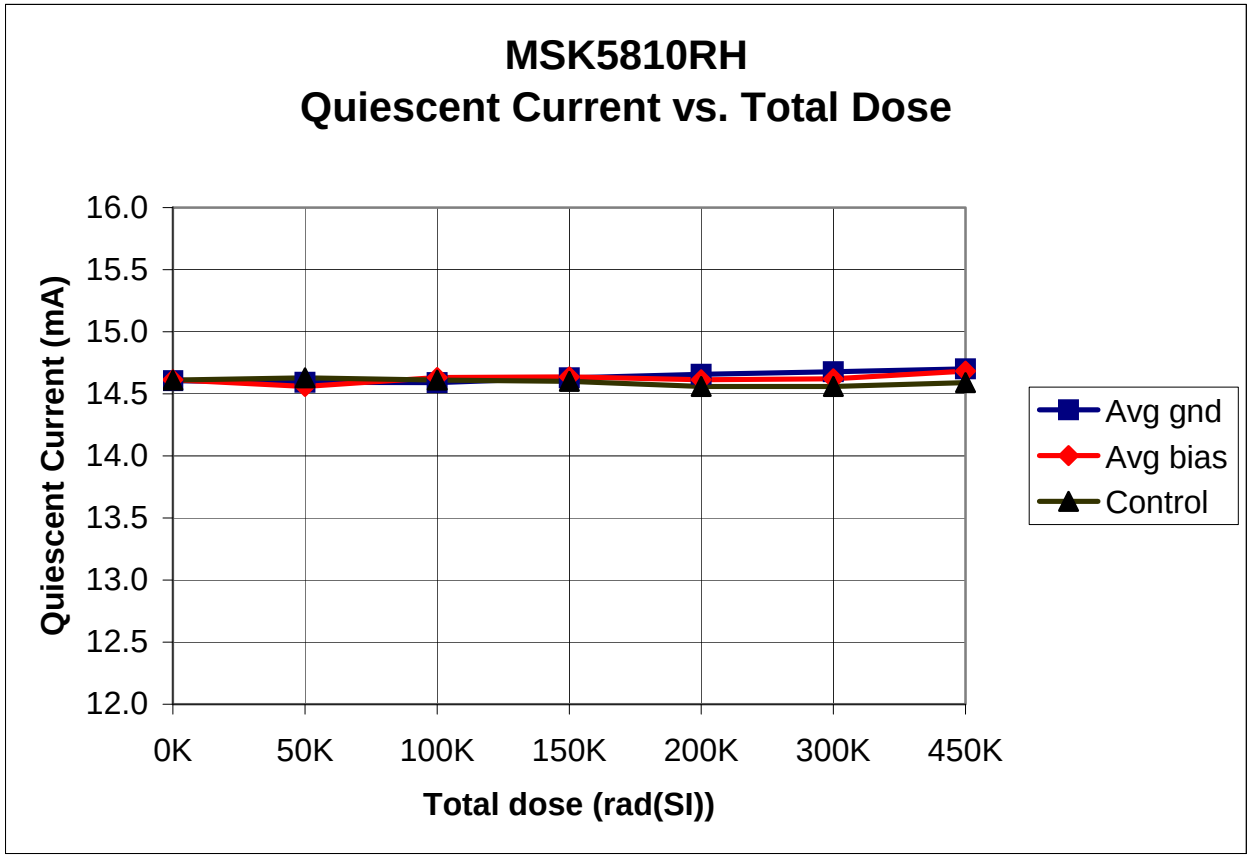
Exposure Length (min:sec)	Incremental Dose rads(Si)	Cumulative Dose rads(Si)
4:40	51,520	51,520
4:40	51,520	103,040
4:40	51,520	154,560
4:40	51,520	206,080
9:20	103,040	309,120
14:00	154,560	463,680

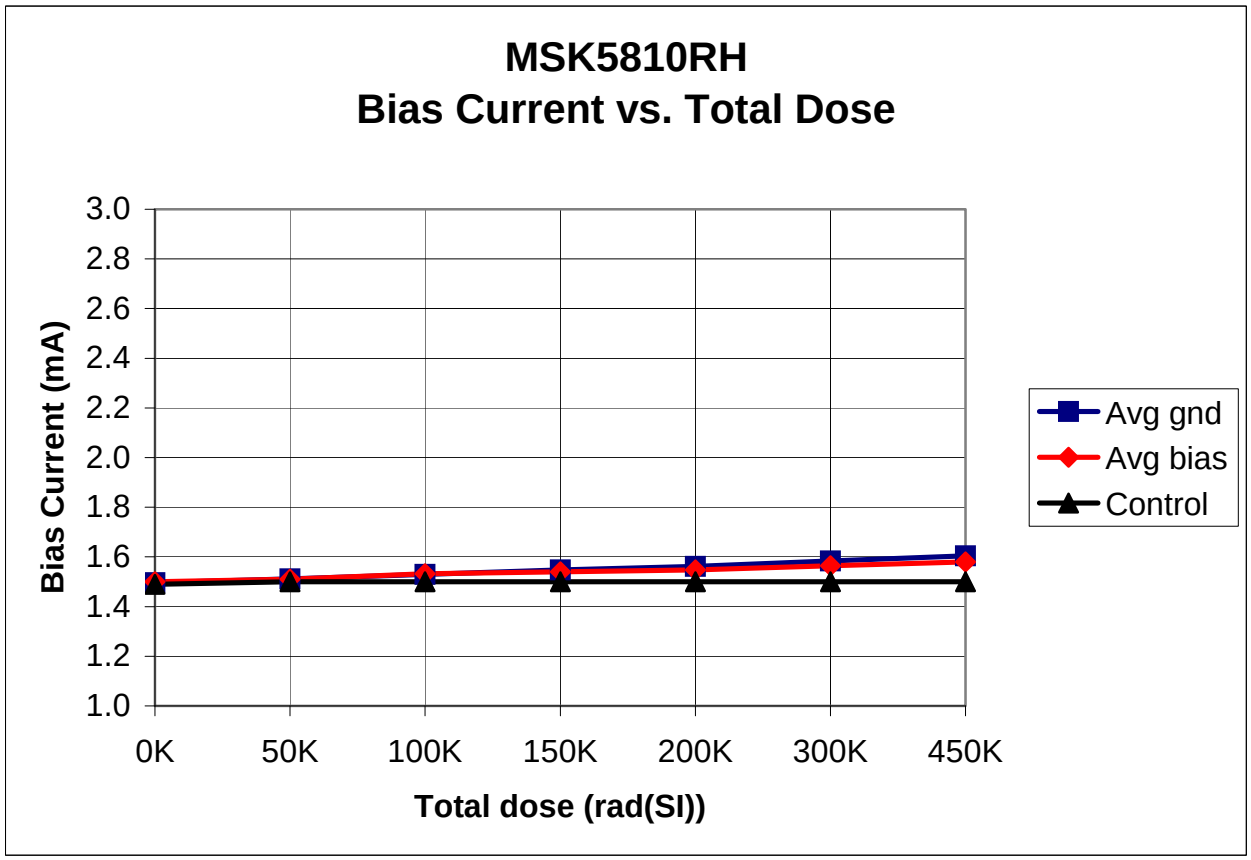
Biased S/N – 0054, 0055, 0056, 0057, 0058

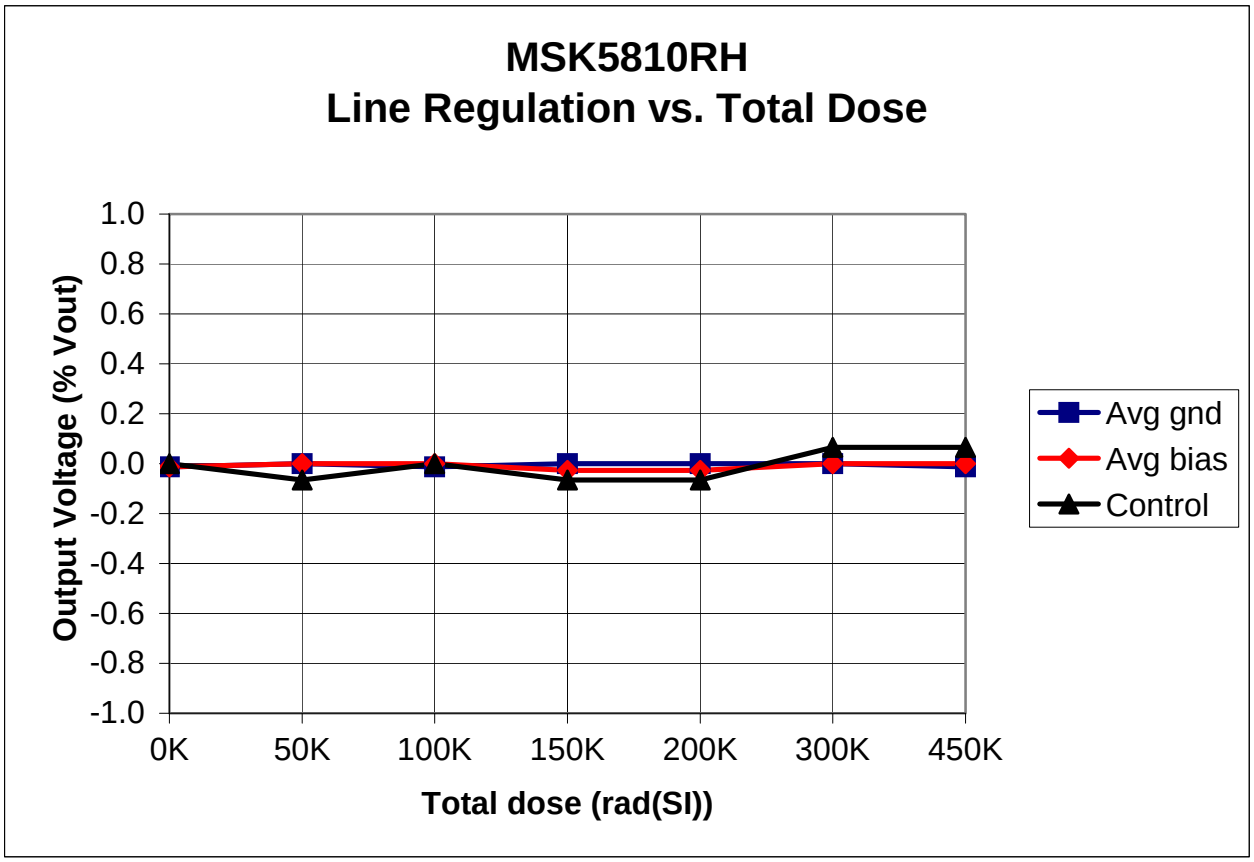
Unbiased S/N – 0059, 0060, 0061, 0062, 0063

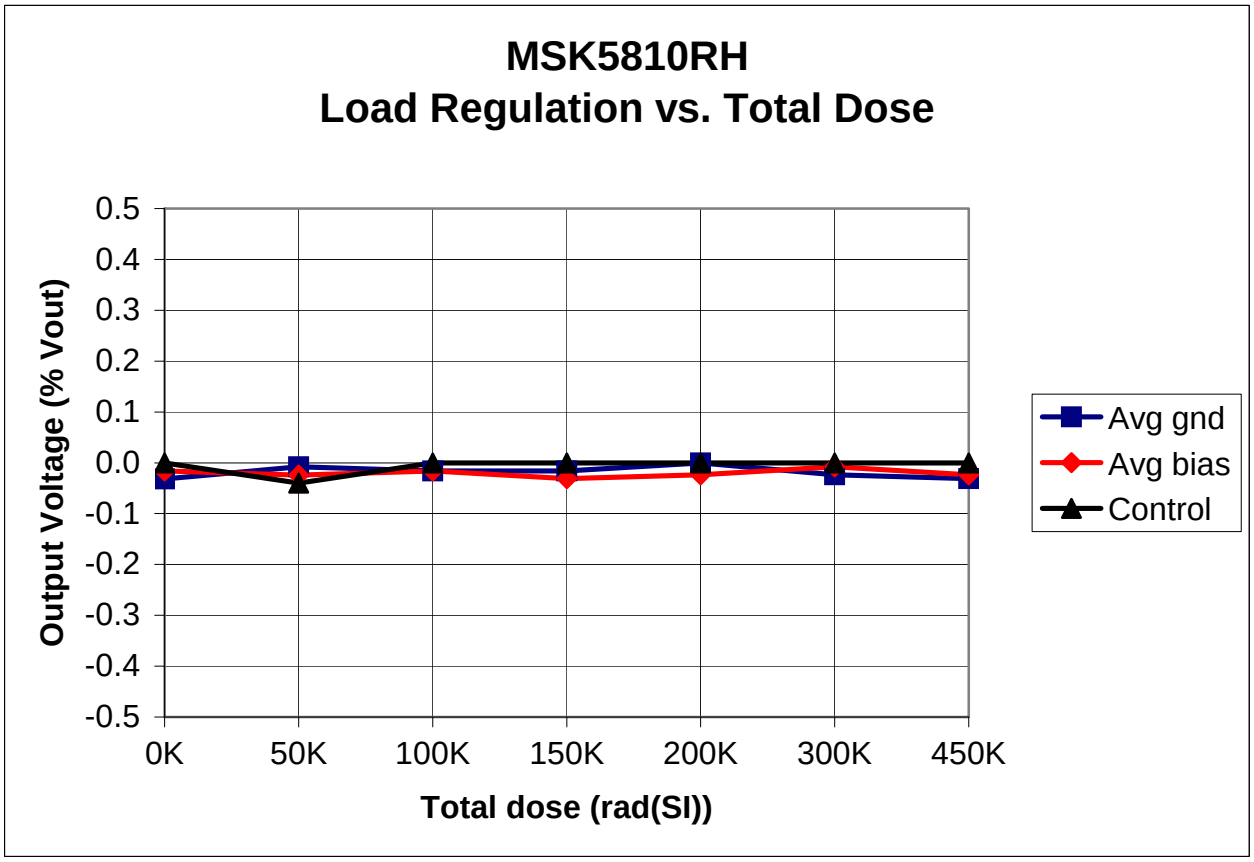
Table 1

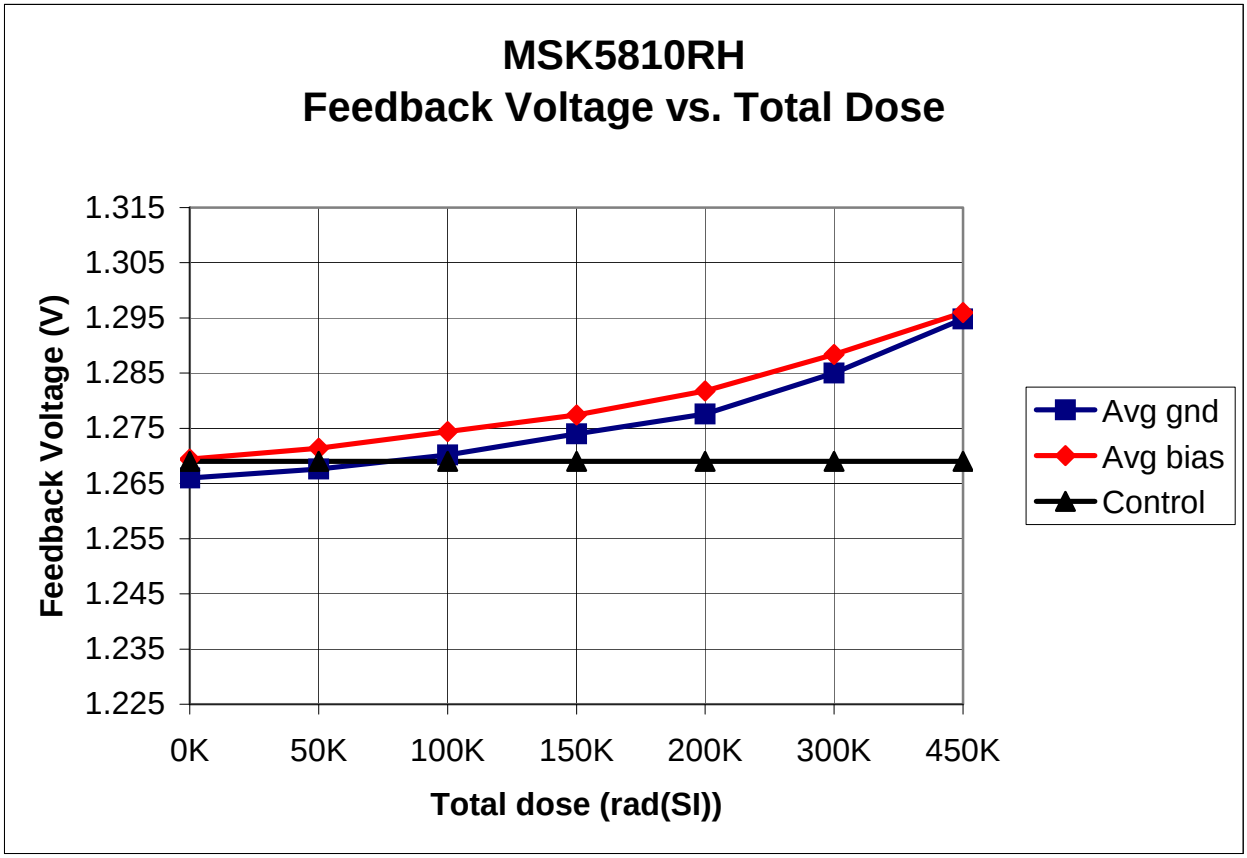
Dose Time, Incremental Dose and Total Cumulative Dose

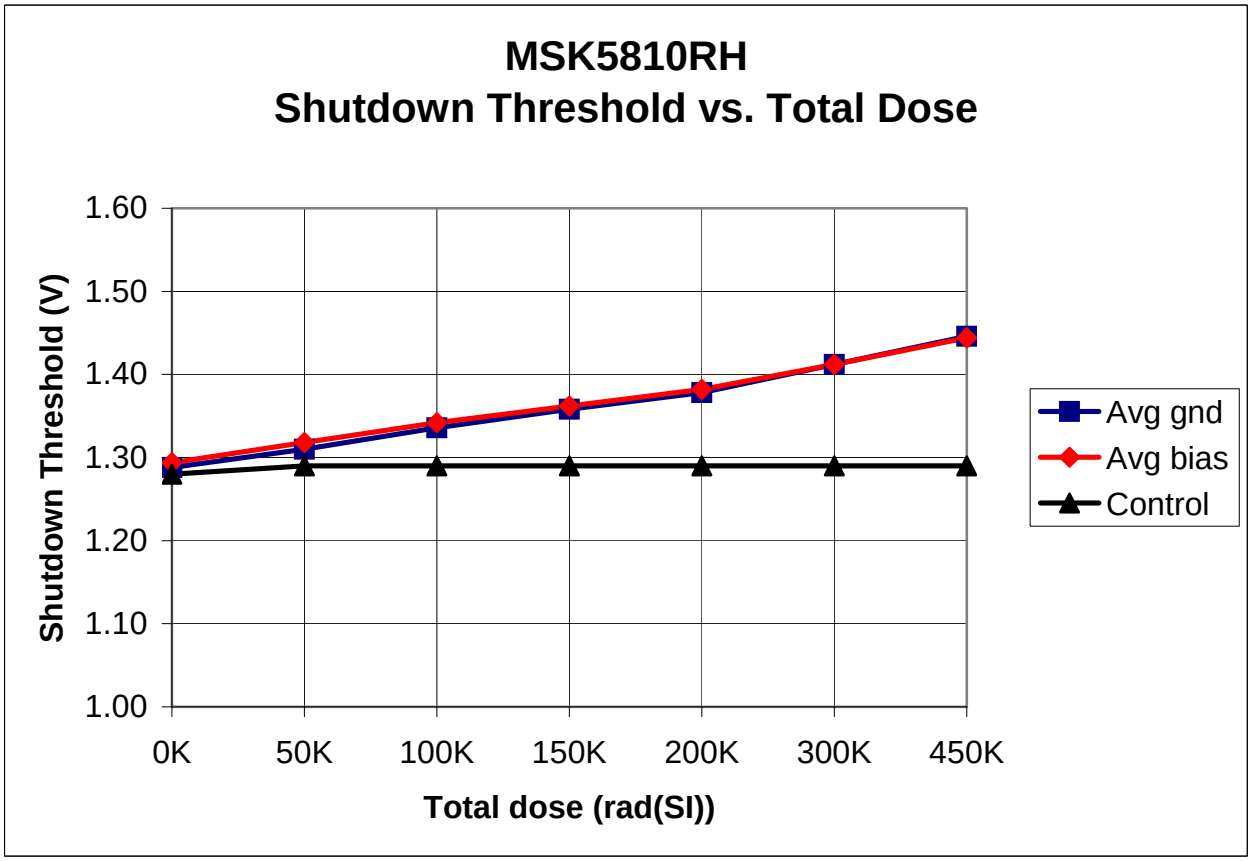

MSK5810RH
Quiescent Current vs. Total Dose
Quiescent Current (mA)
16.0
15.5
15.0
14.5
14.0
13.5
13.0
12.5
12.0
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(SI))
Avg gnd
Avg bias
Control

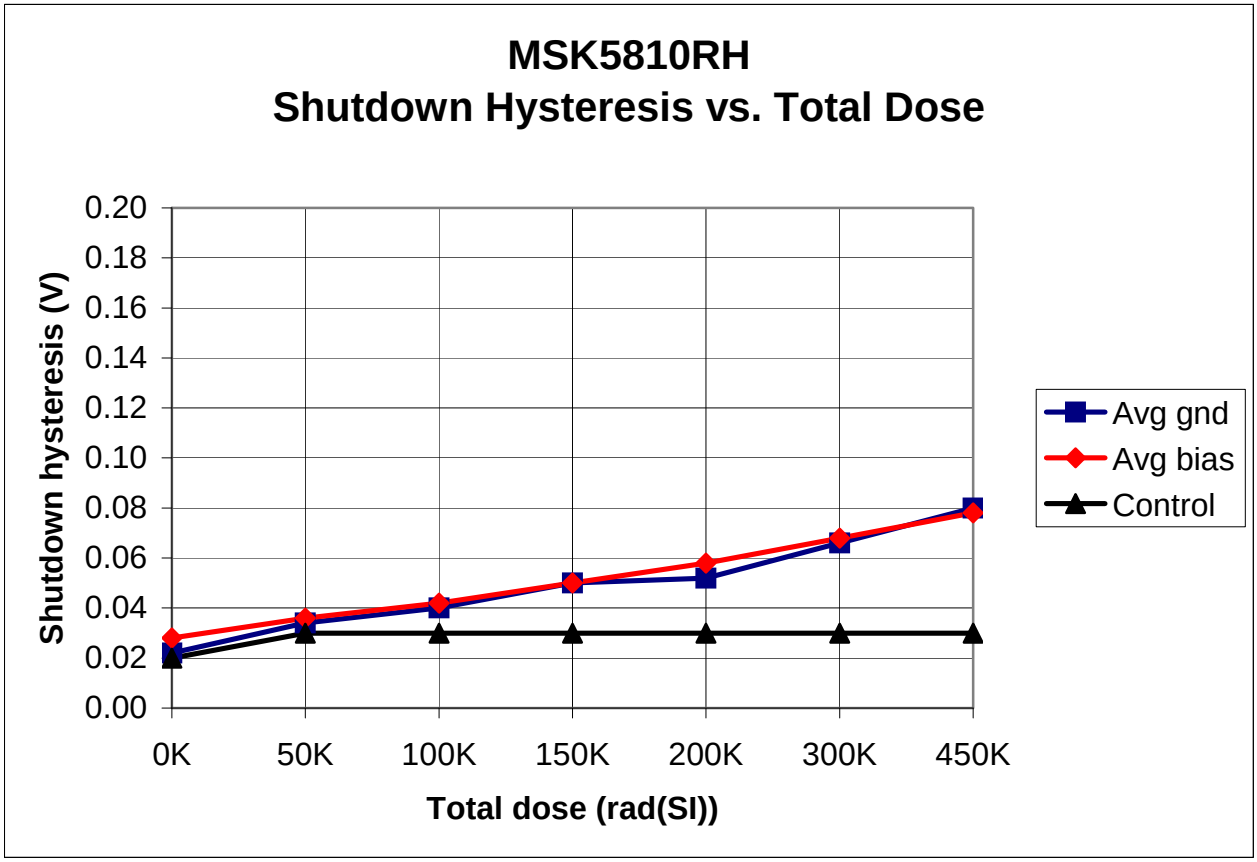

MSK5810RH
Bias Current vs. Total Dose
Bias Current (mA)
3.0
2.8
2.6
2.4
2.2
2.0
1.8
1.6
1.4
1.2
1.0
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(SI))
Avg gnd
Avg bias
Control

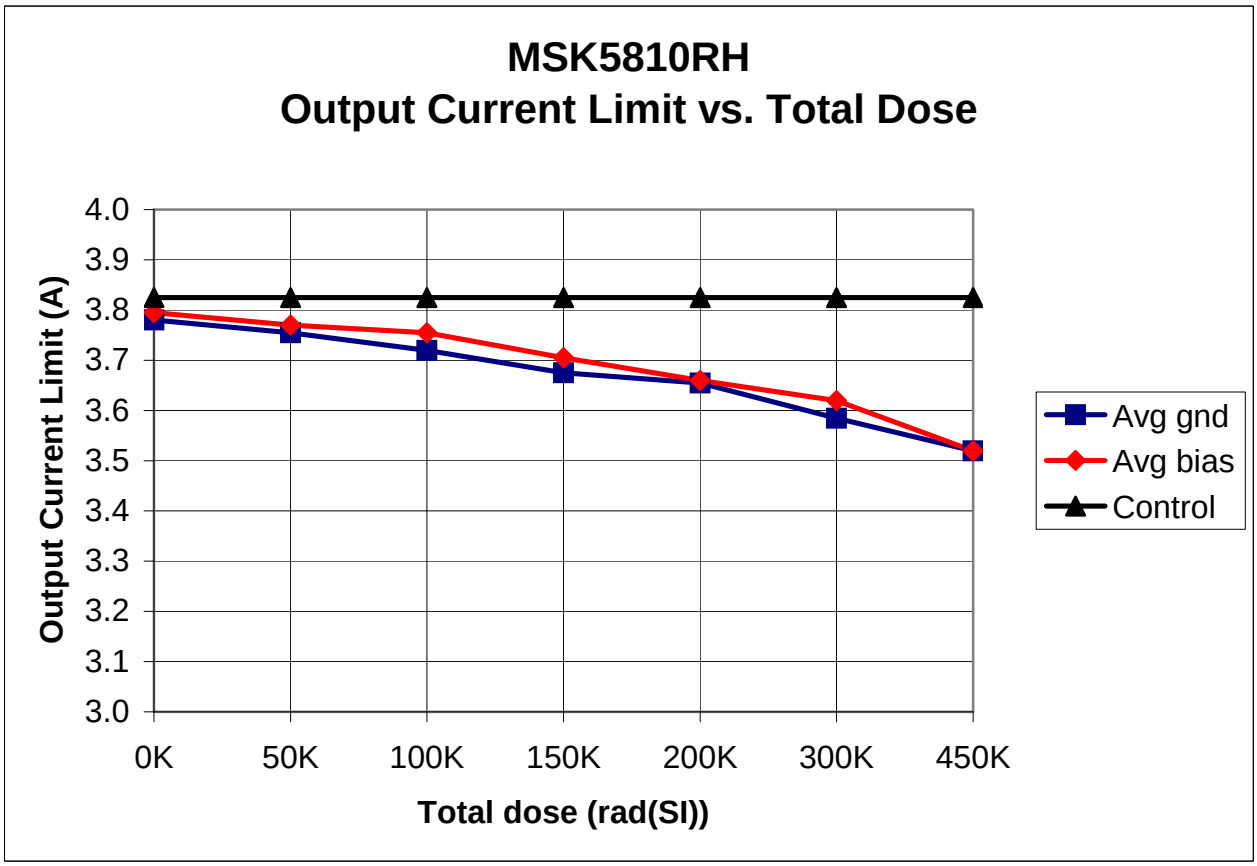

MSK5810RH
Line Regulation vs. Total Dose
Output Voltage (% Vout)
1.0
0.8
0.6
0.4
0.2
0.0
-0.2
-0.4
-0.6
-0.8
-1.0
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(SI))
Avg gnd
Avg bias
Control

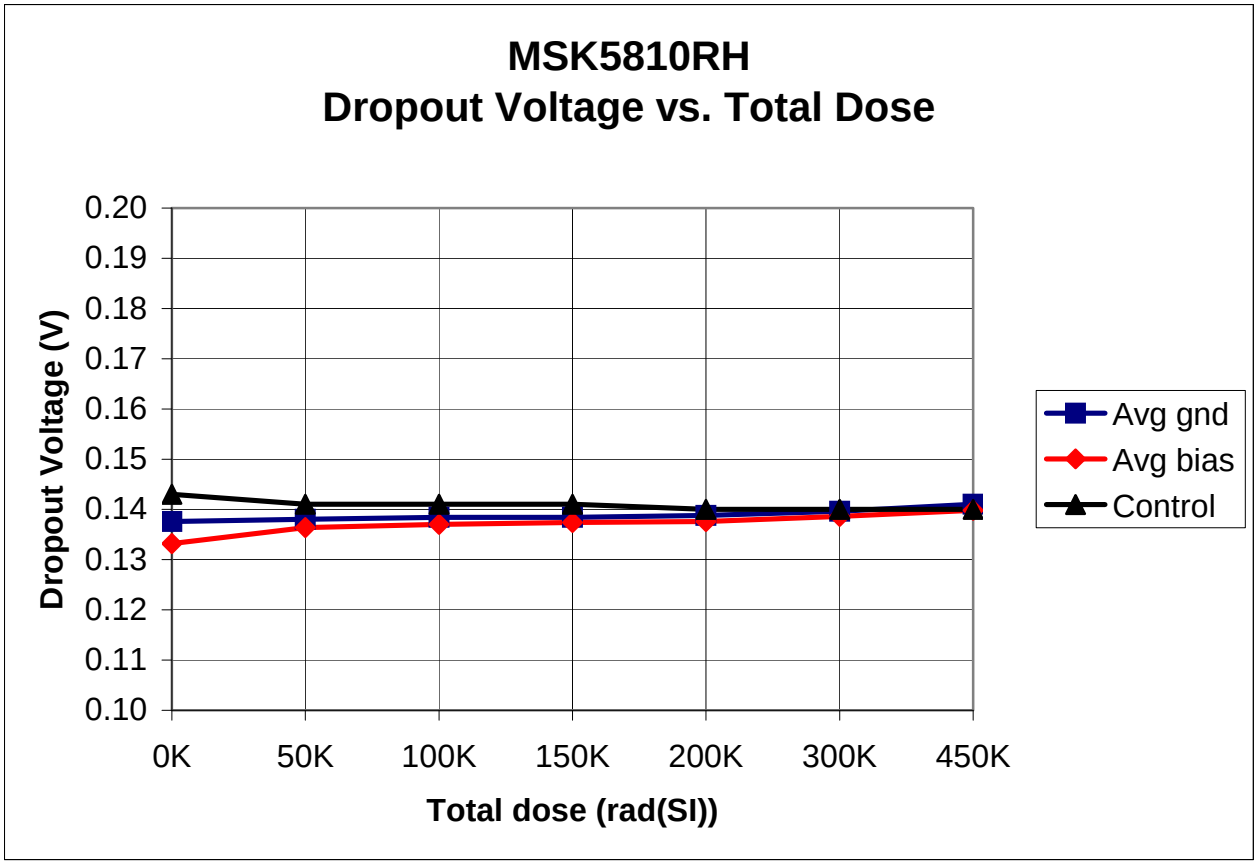

MSK5810RH
Load Regulation vs. Total Dose
Output Voltage (% Vout)
0.5
0.4
0.3
0.2
0.1
0.0
-0.1
-0.2
-0.3
-0.4
-0.5
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(SI))
Avg gnd
Avg bias
Control


MSK5810RH
Feedback Voltage vs. Total Dose
Feedback Voltage (V)
1.315
1.305
1.295
1.285
1.275
1.265
1.255
1.245
1.235
1.225
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(SI))
Avg gnd
Avg bias
Control


MSK5810RH
Shutdown Threshold vs. Total Dose
Shutdown Threshold (V)
1.60
1.50
1.40
1.30
1.20
1.10
1.00
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(SI))
Avg gnd
Avg bias
Control


MSK5810RH
Shutdown Hysteresis vs. Total Dose
Shutdown hysteresis (V)
0.20
0.18
0.16
0.14
0.12
0.10
0.08
0.06
0.04
0.02
0.00
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control


MSK5810RH
Output Current Limit vs. Total Dose
Output Current Limit (A)
4.0
3.9
3.8
3.7
3.6
3.5
3.4
3.3
3.2
3.1
3.0
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control


MSK5810RH
Dropout Voltage vs. Total Dose
Dropout Voltage (V)
0.20
0.19
0.18
0.17
0.16
0.15
0.14
0.13
0.12
0.11
0.10
0K
50K
100K
150K
200K
300K
450K
Total dose (rad(Si))
Avg gnd
Avg bias
Control